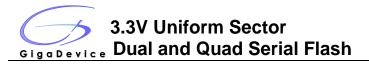
# **GD25Q16C**

**DATASHEET** 



# Contents

1.	FE/	ATURES	4
2.	GE	NERAL DESCRIPTION	5
3.		MORY ORGANIZATION	
4.		VICE OPERATION	
5.	DA	TA PROTECTION	9
ô.	STA	ATUS REGISTER	11
7.	СО	MMANDS DESCRIPTION	13
	7.1.	Write Enable (WREN) (06H)	16
	7.2.	Write Disable (WRDI) (04H)	16
	7.3.	READ STATUS REGISTER (RDSR) (05H or 35H)	16
	7.4.	Write Status Register (WRSR) (01H)	17
	7.5.	Write Enable for Volatile Status Register (50H)	18
	7.6.	READ DATA BYTES (READ) (03H)	18
	7.7.	READ DATA BYTES AT HIGHER SPEED (FAST READ) (0BH)	19
	7.8.	DUAL OUTPUT FAST READ (3BH)	19
	7.9.	QUAD OUTPUT FAST READ (6BH)	20
	7.10.	DUAL I/O FAST READ (BBH)	20
	7.11.	QUAD I/O FAST READ (EBH)	22
	7.12.	QUAD I/O WORD FAST READ (E7H)	23
	7.13.	PAGE PROGRAM (PP) (02H)	24
	7.14.	QUAD PAGE PROGRAM (32H)	25
	7.15.	SECTOR ERASE (SE) (20H)	26
	7.16.	32KB BLOCK ERASE (BE) (52H)	26
	7.17.	64KB BLOCK ERASE (BE) (D8H)	27
	7.18.	CHIP ERASE (CE) (60/C7H)	27
	7.19.	DEEP POWER-DOWN (DP) (B9H)	28
	7.20.	RELEASE FROM DEEP POWER-DOWN OR HIGH PERFORMANCE MODE AND READ DEVICE ID (RDI) (ABH)	28
	7.21.	READ MANUFACTURE ID/ DEVICE ID (REMS) (90H)	30
	7.22.	READ IDENTIFICATION (RDID) (9FH)	30
	7.23.	HIGH PERFORMANCE MODE (HPM) (A3H)	31
	7.24.	CONTINUOUS READ MODE RESET (CRMR) (FFH)	32
	7.25.	READ UNIQUE ID (4BH)	33
	7.26.	PROGRAM/ERASE SUSPEND (PES) (75H)	33
	7.27.	PROGRAM/ERASE RESUME (PER) (7AH)	34
	7.28.	Erase Security Registers (44H)	34
	7.29.	PROGRAM SECURITY REGISTERS (42H)	35
	7.30.	READ SECURITY REGISTERS (48H)	35
	7.31.	ENABLE RESET (66H) AND RESET (99H)	36
	7.32.	READ SERIAL FLASH DISCOVERABLE PARAMETER (5AH)	37

# **GD25Q16C**

8.	ELE	ECTRICAL CHARACTERISTICS	42
8.1	1.	POWER-ON TIMING	42
8.2	2.	INITIAL DELIVERY STATE	42
8.3	3.	DATA RETENTION AND ENDURANCE	42
8.4	4.	ABSOLUTE MAXIMUM RATINGS	43
8.5	5.	CAPACITANCE MEASUREMENT CONDITIONS	43
8.6	5.	DC CHARACTERISTICS	44
8.7	7.	AC CHARACTERISTICS	45
9.	ORI	DERING INFORMATION	48
10.		ACKAGE INFORMATION	
10.	• 4		
10	.1.	PACKAGE SOP8 150MIL	
10	.2.	PACKAGE SOP8 208MIL	50
10	.3.	PACKAGE VSOP8 208MIL	51
10	.4.	PACKAGE DIP8 300MIL	52
10	.5.	PACKAGE USON8 (3*2mm, THICKNESS 0.45mm)	53
10	.6.	PACKAGE USON8 (4*3MM)	54
10	.7.	PACKAGE USON8 (4*4MM)	55
10	.8.	PACKAGE WSON 8 (6*5MM)	56
10	.9.	PACKAGE TFBGA-24BALL (6*4 BALL ARRAY)	57
10	.10.	PACKAGE TFBGA-24BALL (5*5 BALL ARRAY)	58
11.	R	EVISION HISTORY	59

## 1. FEATURES

- ◆ 16M-bit Serial Flash
  - -2048K-byte
  - -256 bytes per programmable page
- · Standard, Dual, Quad SPI
  - -Standard SPI: SCLK, CS#, SI, SO, WP#, HOLD#
  - -Dual SPI: SCLK, CS#, IO0, IO1, WP#, HOLD#
  - -Quad SPI: SCLK, CS#, IO0, IO1, IO2, IO3
- High Speed Clock Frequency
  - -120MHz for fast read with 30PF load
  - -Dual I/O Data transfer up to 240Mbits/s
  - -Quad I/O Data transfer up to 480Mbits/s
- Software/Hardware Write Protection
  - -Write protect all/portion of memory via software
  - -Enable/Disable protection with WP# Pin
  - -Top or Bottom, Sector or Block selection
- · Cycling endurance
  - -Minimum 100,000 Program/Erase Cycles
- Data retention
  - -20-year data retention typical

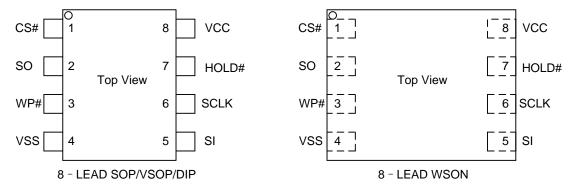
- ◆ Program/Erase Speed
  - -Page Program time: 0.6ms typical
  - -Sector Erase time: 45ms typical
  - -Block Erase time: 0.15/0.25s typical
  - -Chip Erase time: 7s typical
- · Flexible Architecture
  - -Sector of 4K-byte
  - -Block of 32/64k-byte
- ◆ Low Power Consumption
  - -20mA maximum active current
  - -5uA maximum power down current
- Advanced Security Features<sup>(1)</sup>
  - -64-Bit Unique ID for each device
  - -4\*256-Byte Security Registers With OTP Locks
  - -Discoverable parameters(SFDP) register
- ◆ Single Power Supply Voltage
  - -Full voltage range:2.7~3.6V
- Package Information
  - -SOP8 (150mil)
  - -SOP8 (208mil)
  - -VSOP8 (208mil)
  - -DIP8 (300mil)
  - -USON8 (3\*2mm)
  - -USON8 (4\*3mm)
  - -USON8 (4\*4mm)
  - -WSON8 (6\*5mm)
  - -TFBGA-24(6\*4 ball array)
  - -TFBGA-24(5\*5 ball array)

Note: 1.Please contact GigaDevice for details.

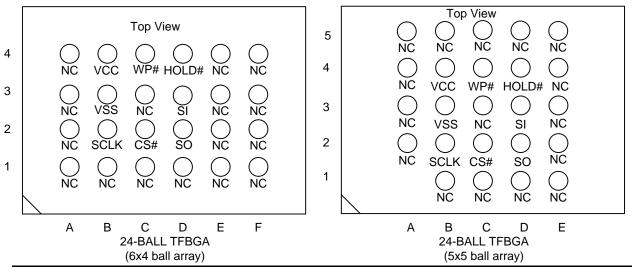
# 2. GENERAL DESCRIPTION

The GD25Q16C(16M-bit) Serial flash supports the standard Serial Peripheral Interface (SPI), and supports the Dual/Quad SPI: Serial Clock, Chip Select, Serial Data I/O0 (SI), I/O1 (SO), I/O2 (WP#), and I/O3 (HOLD#). The Dual I/O data is transferred with speed of 240Mbits/s and the Quad I/O & Quad output data is transferred with speed of 480Mbits/s.

### **CONNECTION DIAGRAM**

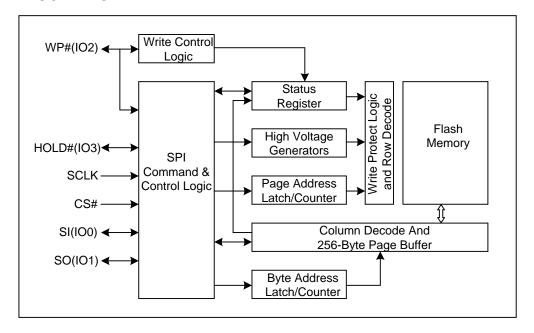


### **PIN DESCRIPTION**



Pin Name	I/O	Description		
CS#	I	Chip Select Input		
SO (IO1)	I/O	Data Output (Data Input Output 1)		
WP# (IO2)	I/O	Write Protect Input (Data Input Output 2)		
VSS		Ground		
SI (IO0)	I/O	Data Input (Data Input Output 0)		
SCLK	I	Serial Clock Input		
HOLD# (IO3)		Hold Input (Data Input Output 3)		
VCC		Power Supply		

## **BLOCK DIAGRAM**





# 3. MEMORY ORGANIZATION

# **GD25Q16C**

Each device has	Each block has	Each sector has	Each page has	
2M	64/32K	4K	256	bytes
8K	256/128	16	-	pages
512	16/8	-	-	sectors
32/64	-	-	-	blocks

# UNIFORM BLOCK SECTOR ARCHITECTURE GD25Q16C 64K Bytes Block Sector Architecture

Block	Sector	Address range		
	511	1FF000H	1FFFFFH	
31				
	496	1F0000H	1F0FFFH	
	495	1EF000H	1EFFFFH	
30				
	480	1E0000H	1E0FFFH	
	47	02F000H	02FFFFH	
2				
	32	020000H	020FFFH	
	31	01F000H	01FFFFH	
1				
	16	010000H	010FFFH	
	15	00F000H	00FFFFH	
0				
	0	000000H	000FFFH	

## 4. DEVICE OPERATION

### **SPI Mode**

### Standard SPI

The GD25Q16C features a serial peripheral interface on 4 signals bus: Serial Clock (SCLK), Chip Select (CS#), Serial Data Input (SI) and Serial Data Output (SO). Both SPI bus mode 0 and 3 are supported. Input data is latched on the rising edge of SCLK and data shifts out on the falling edge of SCLK.

#### **Dual SPI**

The GD25Q16C supports Dual SPI operation when using the "Dual Output Fast Read" and "Dual I/O Fast Read" (3BH and BBH) commands. These commands allow data to be transferred to or from the device at two times the rate of the standard SPI. When using the Dual SPI command the SI and SO pins become bidirectional I/O pins: IOO and IO1.

### **Quad SPI**

The GD25Q16C supports Quad SPI operation when using the "Quad Output Fast Read" (6BH), "Quad I/O Fast Read" (E7H) and "Quad Page Program" (32H) commands. These commands allow data to be transferred to or from the device at four times the rate of the standard SPI. When using the Quad SPI command the SI and SO pins become bidirectional I/O pins: IO0 and IO1, and WP# and HOLD# pins become IO2 and IO3. Quad SPI commands require the non-volatile Quad Enable bit (QE) in Status Register to be set.

#### Hold

The HOLD# function is only available when QE=0, If QE=1, The HOLD# functions is disabled, the pin acts as dedicated data I/O pin.

The HOLD# signal goes low to stop any serial communications with the device, but doesn't stop the operation of write status register, programming, or erasing in progress.

The operation of HOLD, need CS# keep low, and starts on falling edge of the HOLD# signal, with SCLK signal being low (if SCLK is not being low, HOLD operation will not start until SCLK being low). The HOLD condition ends on rising edge of HOLD# signal with SCLK being low (If SCLK is not being low, HOLD operation will not end until SCLK being low).

The SO is high impedance, both SI and SCLK don't care during the HOLD operation, if CS# drives high during HOLD operation, it will reset the internal logic of the device. To re-start communication with chip, the HOLD# must be at high and then CS# must be at low.

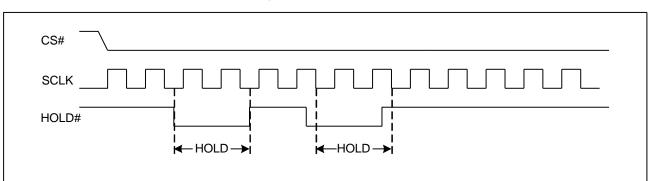


Figure 1. Hold Condition

# 5. DATA PROTECTION

The GD25Q16C provide the following data protection methods:

- Write Enable (WREN) command: The WREN command is set the Write Enable Latch bit (WEL). The WEL bit will return to reset by the following situation:
  - -Power-Up
  - -Write Disable (WRDI)
  - -Write Status Register (WRSR)
  - -Page Program (PP)
  - -Sector Erase (SE) / Block Erase (BE) / Chip Erase (CE)
- Software Protection Mode: The Block Protect (BP4, BP3, BP2, BP1, and BP0) bits define the section of the memory array that can be read but not change.
- ♦ Hardware Protection Mode: WP# going low to protected the BP0~BP4 bits and SRP0~1 bits.
- Deep Power-Down Mode: In Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down Mode command.

Table1.0 GD25Q16C Protected area size (CMP=0)

	Table1.0 GD25Q16C Protected area size (CMP=0)  Status Register Content  Memory Content											
;	Status F	Register	Conten	t		Memory Conte	nt					
BP4	BP3	BP2	BP1	BP0	Blocks	Addresses	Density	Portion				
Х	Х	0	0	0	NONE	NONE	NONE	NONE				
0	0	0	0	1	31	1F0000H-1FFFFFH	64KB	Upper 1/32				
0	0	0	1	0	30 to 31	1E0000H-1FFFFFH	128KB	Upper 1/16				
0	0	0	1	1	28 to 31	1C0000H-1FFFFFH	256KB	Upper 1/8				
0	0	1	0	0	24 to 31	180000H-1FFFFFH	512KB	Upper 1/4				
0	0	1	0	1	16 to 31	100000H-1FFFFFH	1M	Upper 1/2				
0	1	0	0	1	0	000000H-00FFFFH	64KB	Lower 1/32				
0	1	0	1	0	0 to 1	000000H-01FFFFH	128KB	Lower 1/16				
0	1	0	1	1	0 to 3	000000H-03FFFFH	256KB	Lower 1/8				
0	1	1	0	0	0 to 7	000000H-07FFFFH	512KB	Lower 1/4				
0	1	1	0	1	0 to 15	000000H-0FFFFFH	1M	Lower 1/2				
Х	Х	1	1	Х	0 to 31	000000H-1FFFFFH	2M	ALL				
1	0	0	0	1	31	1FF000H-1FFFFFH	4KB	Top Block				
1	0	0	1	0	31	1FE000H-1FFFFFH	8KB	Top Block				
1	0	0	1	1	31	1FC000H-1FFFFFH	16KB	Top Block				
1	0	1	0	Х	31	1F8000H-1FFFFFH	32KB	Top Block				
1	1	0	0	1	0	000000H-000FFFH	4KB	Bottom Block				
1	1	0	1	0	0	000000H-001FFFH	8KB	Bottom Block				
1	1	0	1	1	0	000000H-003FFFH	16KB	Bottom Block				
1	1	1	0	Х	0	000000H-007FFFH	32KB	Bottom Block				



# 3.3V Uniform Sector Giga Device Dual and Quad Serial Flash

**GD25Q16C** 

Table1.1 GD25Q16C Protected area size (CMP=1)

:	Status F	Register	Conten	t	Memory Content				
BP4	BP4 BP3 BP2 BP1 BP0		Blocks	Addresses	Density	Portion			
Х	Х	0	0	0	0 to 31	000000H-1FFFFFH	2M	ALL	
0	0	0	0	1	0 to 30	000000H-1EFFFFH	1984KB	Lower 31/32	
0	0	0	1	0	0 to 29	000000H-1DFFFFH	1920KB	Lower 15/16	
0	0	0	1	1	0 to 27	000000H-1BFFFFH	1792KB	Lower 7/8	
0	0	1	0	0	0 to 23	000000H-17FFFFH	1536KB	Lower 3/4	
0	0	1	0	1	0 to 15	000000H-0FFFFH	1M	Lower 1/2	
0	1	0	0	1	1 to 31	010000H-1FFFFFH	1984KB	Upper 31/32	
0	1	0	1	0	2 to 31	020000H-1FFFFFH	1920KB	Upper 15/16	
0	1	0	1	1	4 to 31	040000H-1FFFFFH	1792KB	Upper 7/8	
0	1	1	0	0	8 to 31	080000H-1FFFFFH	1536KB	Upper 3/4	
0	1	1	0	1	16 to 31	100000H-1FFFFFH	1M	Upper 1/2	
Х	Х	1	1	Х	NONE	NONE	NONE	NONE	
1	0	0	0	1	0 to 31	000000H-1FEFFFH	2044KB	Lower 511/512	
1	0	0	1	0	0 to 31	000000H-1FDFFFH	2040KB	Lower 255/256	
1	0	0	1	1	0 to 31	000000H-1FBFFFH	2032KB	Lower 127/128	
1	0	1	0	Х	0 to 31	000000H-1F7FFFH	2016KB	Lower 63/64	
1	1	0	0	1	0 to 31	001000H-1FFFFFH	2044KB	Upper 511/512	
1	1	0	1	0	0 to 31	002000H-1FFFFFH	2040KB	Upper 255/256	
1	1	0	1	1	0 to 31	004000H-1FFFFFH	2032KB	Upper 127/128	
1	1	1	0	Х	0 to 31	008000H-1FFFFFH	2016KB	Upper 63/64	



# 6. STATUS REGISTER

S15	S14	S13	S12	S11	S10	S9	S8
SUS	СМР	НРМ	Reserved	Reserved	LB	QE	SRP1
<b>S</b> 7	S6	<b>S</b> 5	<b>S</b> 4	<b>S</b> 3	S2	S1	S0

The status and control bits of the Status Register are as follows:

#### WIP bit.

The Write in Progress (WIP) bit indicates whether the memory is busy in program/erase/write status register progress. When WIP bit sets to 1, means the device is busy in program/erase/write status register progress, when WIP bit sets 0, means the device is not in program/erase/write status register progress.

### WEL bit.

The Write Enable Latch (WEL) bit indicates the status of the internal Write Enable Latch. When set to 1 the internal Write Enable Latch is set, when set to 0 the internal Write Enable Latch is reset and no Write Status Register, Program or Erase command is accepted.

### BP4, BP3, BP2, BP1, BP0 bits.

The Block Protect (BP4, BP3, BP2, BP1, and BP0) bits are non-volatile. They define the size of the area to be software protected against Program and Erase commands. These bits are written with the Write Status Register (WRSR) command. When the Block Protect (BP4, BP3, BP2, BP1, BP0) bits are set to 1, the relevant memory area (as defined in Table1).becomes protected against Page Program (PP), Sector Erase (SE) and Block Erase (BE) commands. The Block Protect (BP4, BP3, BP2, BP1, and BP0) bits can be written provided that the Hardware Protected mode has not been set. The Chip Erase (CE) command is executed, only if the Block Protect (BP2, BP1, and BP0) bits are 0 and CMP=0.

### SRP1, SRP0 bits.

The Status Register Protect (SRP1 and SRP0) bits are non-volatile Read/Write bits in the status register. The SRP bits control the method of write protection: software protection, hardware protection, power supply lock-down or one time programmable protection.

SRP1	SRP0	#WP	Status Register	Description
0	0	Х	Software Protected	The Status Register can be written to after a Write Enable command, WEL=1.(Default)
0	1	0	Hardware Protected	WP#=0, the Status Register locked and can not be written to.
0	1	1	Hardware Unprotected	WP#=1, the Status Register is unlocked and can be written to after a Write Enable command, WEL=1.
1	0	Х	Power Supply Lock-Down(1) (2)	Status Register is protected and can not be written to again until the next Power-Down, Power-Up cycle.
1	1	Х	One Time Program(2)	Status Register is permanently protected and can not be written to.

# NOTE:

- 1. When SRP1, SRP0= (1, 0), a Power-Down, Power-Up cycle will change SRP1, SRP0 to (0, 0) state.
- 2. This feature is available on special order. Please contact GigaDevice for details.

### QE bit.

The Quad Enable (QE) bit is a non-volatile Read/Write bit in the Status Register that allows Quad operation. When

**GD25Q16C** 

the QE bit is set to 0 (Default) the WP# pin and HOLD# pin are enable. When the QE pin is set to 1, the Quad IO2 and IO3 pins are enabled. (The QE bit should never be set to 1 during standard SPI or Dual SPI operation if the WP# or HOLD# pins are tied directly to the power supply or ground)

### LB bit.

The LB bit is a non-volatile One Time Program (OTP) bit in Status Register (S10) that provide the write protect control and status to the Security Registers. The default state of LB is 0, the security registers are unlocked. LB can be set to 1 individually using the Write Register instruction. LB is One Time Programmable, once it's set to 1, the Security Registers will become read-only permanently.

### **CMP** bit

The CMP bit is a non-volatile Read/Write bit in the Status Register (S14). It is used in conjunction the BP4-BP0 bits to provide more flexibility for the array protection. Please see the Status registers Memory Protection table for details. The default setting is CMP=0.

### **HPF** bit

The High Performance Flag (HPF) bit indicates the status of High Performance Mode (HPM). When HPF bit sets to 1, it means the device is in High Performance Mode, when HPF bit sets 0 (default), it means the device is not in High Performance Mode.

#### SUS bit

The SUS bit is a read only bit in the status register (S15) that is set to 1 after executing an Erase/Program Suspend (75H) command. The SUS bit is cleared to 0 by Erase/Program Resume (7AH) command as well as a power-down, power-up cycle.

## 7. COMMANDS DESCRIPTION

All commands, addresses and data are shifted in and out of the device, beginning with the most significant bit on the first rising edge of SCLK after CS# is driven low. Then, the one-byte command code must be shifted in to the device, most significant bit first on SI, each bit being latched on the rising edges of SCLK.

See Table2, every command sequence starts with a one-byte command code. Depending on the command, this might be followed by address bytes, or by data bytes, or by both or none. CS# must be driven high after the last bit of the command sequence has been shifted in. For the commands of Read, Fast Read, Read Status Register or Release from Deep Power-Down, and Read Device ID, the shifted-in command sequence is followed by a data-out sequence. CS# can be driven high after any bit of the data-out sequence is being shifted out.

For the commands of Page Program, Sector Erase, Block Erase, Chip Erase, Write Status Register, Write Enable, Write Disable or Deep Power-Down command, CS# must be driven high exactly at a byte boundary, otherwise the command is rejected, and is not executed. That means CS# must be driven high when the number of clock pulses after CS# being driven low is an exact multiple of eight. For Page Program, if CS# is driven high at any time the input byte is not a full byte, nothing will happen and WEL will not be reset.

Table2. Commands (Standard/Dual/Quad SPI)

Command Name	Byte 1	Byte 2	Byte 3	Byte 4	Byte 5	Byte 6	n-Bytes
Write Enable	06H						
Write Disable	04H						
Volatile SR	50H						
Write Enable							
Read Status Register	05H	(S7-S0)					(continuous)
Read Status Register-1	35H	(S15-S8)					(continuous)
Write Status Register	01H	(S7-S0)	(S15-S8)				
Read Data	03H	A23-A16	A15-A8	A7-A0	(D7-D0)	(Next byte)	(continuous)
Fast Read	0BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	(continuous)
Dual Output	3BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) <sup>(1)</sup>	(continuous)
Fast Read Dual I/O	DDII	A23-A8 <sup>(2)</sup>	47.40	(D7-D0) <sup>(1)</sup>			(continuous)
Fast Read	BBH	A23-A8(2)	A7-A0 M7-M0 <sup>(2)</sup>	(07-00)(1)			(continuous)
Quad Output	6BH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0) <sup>(3)</sup>	(continuous)
Fast Read	ОБП	A23-A16	A15-A6	A7-A0	dummy	(07-00)(4)	(continuous)
Quad I/O	EBH	A23-A0	dummy <sup>(5)</sup>	(D7-D0) <sup>(3)</sup>			(continuous)
Fast Read	LDII	M7-M0 <sup>(4)</sup>	dummy	(67-60)			(continuous)
Quad I/O Word	E7H	A23-A0	dummy <sup>(6)</sup>	(D7-D0) <sup>(3)</sup>			(continuous)
Fast Read <sup>(7)</sup>		M7-M0 <sup>(4)</sup>		(= 1 = 1)			(**************************************
Continuous Read Mode Reset	FFH						
Page Program	02 H	A23-A16	A15-A8	A7-A0	(D7-D0)	Next byte	
Quad Page Program	32H	A23-A16	A15-A8	A7-A0	(D7-D0) <sup>(3)</sup>	•	
Sector Erase	20H	A23-A16	A15-A8	A7-A0			
Block Erase(32K)	52H	A23-A16	A15-A8	A7-A0			
Block Erase(64K)	D8H	A23-A16	A15-A8	A7-A0			
Chip Erase	C7/60						
	Н						
Enable Reset	66H						
Reset	99H						
Program/Erase	75H						
Suspend							
Program/Erase Resume	7AH						
Deep Power-Down	В9Н						

# 3.3V Uniform Sector Gigabevice Dual and Quad Serial Flash

# **GD25Q16C**

							1
Release From Deep	ABH	dummy	dummy	dummy	(DID7-		(continuous)
Power-Down, And					DID0)		
Read Device ID							
Release From Deep	ABH						
Power-Down							
Manufacturer/	90H	dummy	dummy	00H	(MID7-	(DID7-	(continuous)
Device ID					MID0)	DID0)	
Read Unique ID	4BH	dummy	dummy	dummy	dummy	(UID127-	
						D0)	
High Performance	АЗН	dummy	dummy	dummy			
Mode							
Read Serial Flash	5AH	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	(continuous)
Discoverable							
Parameter							
Read Identification	9FH	(MID7-	(JDID15-	(JDID7-			(continuous)
		M0)	JDID8)	JDID0)			
Erase Security	44H	A23-A16	A15-A8	A7-A0			
Registers(8)							
Program Security	42H	A23-A16	A15-A8	A7-A0	(D7-D0)	(D7-D0)	
Registers(8)							
Read Security	48H	A23-A16	A15-A8	A7-A0	dummy	(D7-D0)	
Registers(8)							

### NOTE:

1. Dual Output data

IO0 = (D6, D4, D2, D0)

IO1 = (D7, D5, D3, D1)

2. Dual Input Address

IO0 = A22, A20, A18, A16, A14, A12, A10, A8 A6, A4, A2, A0, M6, M4, M2, M0

IO1 = A23, A21, A19, A17, A15, A13, A11, A9 A7, A5, A3, A1, M7, M5, M3, M1

3. Quad Output Data

IO0 = (D4, D0, ....)

IO1 = (D5, D1, ....)

IO2 = (D6, D2, ....)

IO3 = (D7, D3,....)

4. Quad Input Address

IO0 = A20, A16, A12, A8, A4, A0, M4, M0

IO1 = A21, A17, A13, A9, A5, A1, M5, M1

IO2 = A22, A18, A14, A10, A6, A2, M6, M2

IO3 = A23, A19, A15, A11, A7, A3, M7, M3

5. Fast Read Quad I/O Data

IO0 = (x, x, x, x, D4, D0,...)

IO1 = (x, x, x, x, D5, D1,...)

IO2 = (x, x, x, x, D6, D2,...)

IO3 = (x, x, x, x, D7, D3,...)

6. Fast Word Read Quad I/O Data

IO0 = (x, x, D4, D0,...)

IO1 = (x, x, D5, D1,...)

IO2 = (x, x, D6, D2,...)



**GD25Q16C** 

IO3 = (x, x, D7, D3,...)

- 7. Fast Word Read Quad I/O Data: the lowest address bit must be 0.
- 8. Security Registers Address:

Security Register0: A23-A16=00H, A15-A8=00H, A7-A0= Byte Address;

Security Register1: A23-A16=00H, A15-A8=01H, A7-A0= Byte Address;

Security Register2: A23-A16=00H, A15-A8=02H, A7-A0= Byte Address;

Security Register3: A23-A16=00H, A15-A8=03H, A7-A0= Byte Address.

9. Address, Continuous Read Mode bits, Dummy bits, Manufacture ID and Device ID

IO0 = (A20, A16, A12, A8, A4, A0, M4, M0, x, x, x, x, MID4, MID0, DID4, DID0, ...)

IO1 = (A21, A17, A13, A9, A5, A1, M5, M1, x, x, x, x, MID5, MID1, DID5, DID1, ...)

IO2 = (A22, A18, A14, A10, A6, A2, M6, M2, x, x, x, x, MID6, MID2, DID6, DID2, ...)

IO3 = (A23, A19, A15, A11, A7, A3, M7, M3, x, x, x, x, MID7, MID3, DID7, DID3, ...)

## **Table of ID Definitions:**

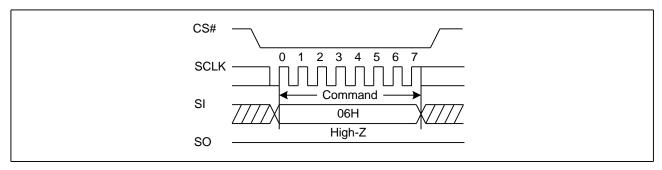
### **GD25Q16C**

Operation Code	MID7-MID0	ID15-ID8	ID7-ID0
9FH	C8	40	15
90H	C8		14
ABH			14

# 7.1. Write Enable (WREN) (06H)

The Write Enable (WREN) command is for setting the Write Enable Latch (WEL) bit. The Write Enable Latch (WEL) bit must be set prior to every Page Program (PP), Sector Erase (SE), Block Erase (BE), Chip Erase (CE), Write Status Register (WRSR) and Erase/Program Security Registers command. The Write Enable (WREN) command sequence: CS# goes low → sending the Write Enable command → CS# goes high.

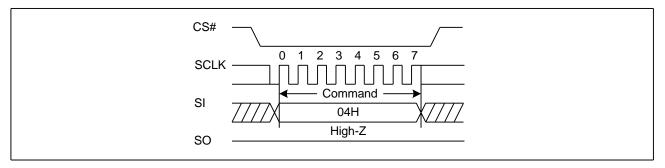
Figure 2. Write Enable Sequence Diagram



# 7.2. Write Disable (WRDI) (04H)

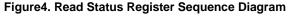
The Write Disable command is for resetting the Write Enable Latch (WEL) bit. The Write Disable command sequence: CS# goes low →Sending the Write Disable command →CS# goes high. The WEL bit is reset by following condition: Power-up and upon completion of the Write Status Register, Page Program, Sector Erase, Block Erase, Chip Erase, Erase/Program Security Registers and Reset commands.

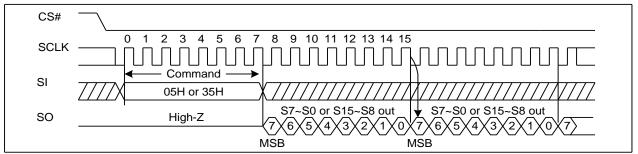
Figure 3. Write Disable Sequence Diagram



# 7.3. Read Status Register (RDSR) (05H or 35H)

The Read Status Register (RDSR) command is for reading the Status Register. The Status Register may be read at any time, even while a Program, Erase or Write Status Register cycle is in progress. When one of these cycles is in progress, it is recommended to check the Write In Progress (WIP) bit before sending a new command to the device. It is also possible to read the Status Register continuously. For command code "05H", the SO will output Status Register bits S7~S0. The command code "35H", the SO will output Status Register bits S15~S8.





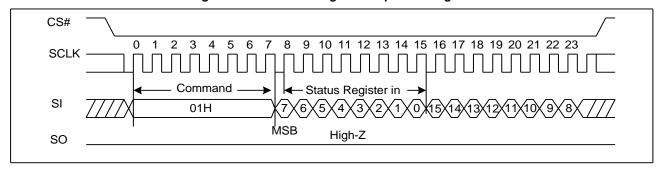
# 7.4. Write Status Register (WRSR) (01H)

The Write Status Register (WRSR) command allows new values to be written to the Status Register. Before it can be accepted, a Write Enable (WREN) command must previously have been executed. After the Write Enable (WREN) command has been decoded and executed, the device sets the Write Enable Latch (WEL).

The Write Status Register (WRSR) command has no effect on S15, S1 and S0 of the Status Register. CS# must be driven high after the eighth or sixteen bit of the data byte has been latched in. If not, the Write Status Register (WRSR) command is not executed. If CS# is driven high after eighth bit of the data byte, the CMP and QE bit will be cleared to 0. As soon as CS# is driven high, the self-timed Write Status Register cycle (whose duration is tw) is initiated. While the Write Status Register cycle is in progress, the Status Register may still be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Write Status Register cycle, and is 0 when it is completed. When the cycle is completed, the Write Enable Latch (WEL) is reset.

The Write Status Register (WRSR) command allows the user to change the values of the Block Protect (BP4, BP3, BP2, BP1, BP0) bits, to define the size of the area that is to be treated as read-only, as defined in Table1. The Write Status Register (WRSR) command also allows the user to set or reset the Status Register Protect (SRP) bit in accordance with the Write Protect (WP#) signal. The Status Register Protect (SRP) bit and Write Protect (WP#) signal allow the device to be put in the Hardware Protected Mode. The Write Status Register (WRSR) command is not executed once the Hardware Protected Mode is entered.

Figure 5. Write Status Register Sequence Diagram



# 7.5. Write Enable for Volatile Status Register (50H)

The non-volatile Status Register bits can also be written to as volatile bits. This gives more flexibility to change the system configuration and memory protection schemes quickly without waiting for the typical non-volatile bit write cycles or affecting the endurance of the Status Register non-volatile bits. The Write Enable for Volatile Status Register command must be issued prior to a Write Status Register command. The Write Enable for Volatile Status Register command will not set the Write Enable Latch bit, it is only valid for the Write Status Register command to change the volatile Status Register bit values.

CS#

SCLK

0 1 2 3 4 5 6 7

Command(50H) →

SI

SO

High-Z

Figure 4. Write Enable for Volatile Status Register Sequence Diagram

# 7.6. Read Data Bytes (READ) (03H)

The Read Data Bytes (READ) command is followed by a 3-byte address (A23-A0), each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency f<sub>R</sub>, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The whole memory can, therefore, be read with a single Read Data Bytes (READ) command. Any Read Data Bytes (READ) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.

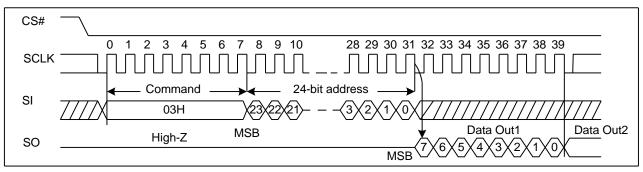


Figure 5. Read Data Bytes Sequence Diagram

# 7.7. Read Data Bytes at Higher Speed (Fast Read) (0BH)

The Read Data Bytes at Higher Speed (Fast Read) command is for quickly reading data out. It is followed by a 3-byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fc, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

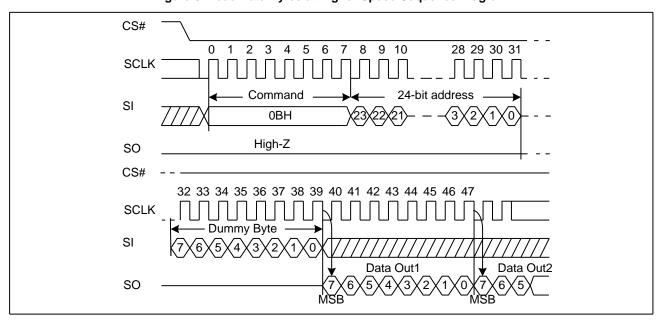


Figure 6. Read Data Bytes at Higher Speed Sequence Diagram

# 7.8. Dual Output Fast Read (3BH)

The Dual Output Fast Read command is followed by 3-byte address (A23-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in followed Figure 9. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

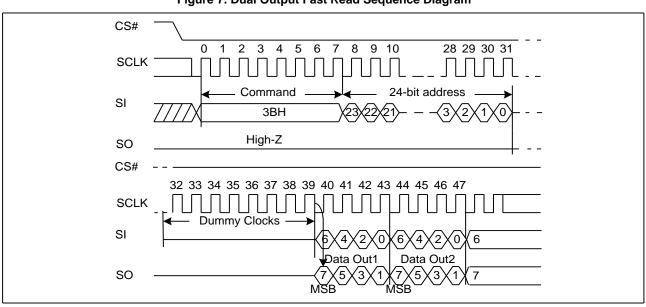


Figure 7. Dual Output Fast Read Sequence Diagram

# 7.9. Quad Output Fast Read (6BH)

The Quad Output Fast Read command is followed by 3-byte address (A23-A0) and a dummy byte, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO3, IO2, IO1 and IO0. The command sequence is shown in followed Figure 10. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

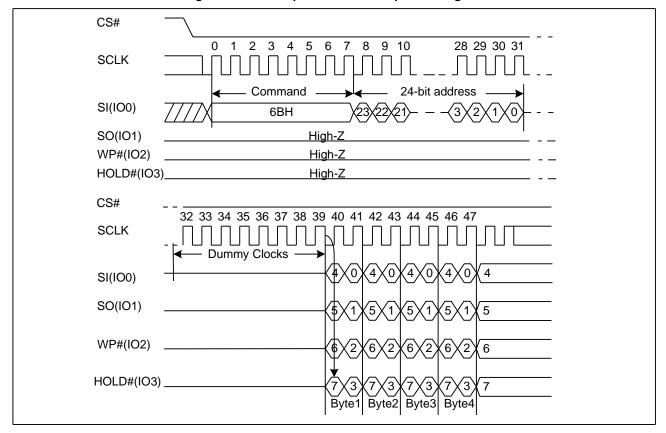


Figure 8. Quad Output Fast Read Sequence Diagram

# 7.10. Dual I/O Fast Read (BBH)

The Dual I/O Fast Read command is similar to the Dual Output Fast Read command but with the capability to input the 3-byte address (A23-0) and a "Continuous Read Mode" byte 2-bit per clock by SI and SO, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 2-bit per clock cycle from SI and SO. The command sequence is shown in followed Figure 11. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out.

### **Dual I/O Fast Read with "Continuous Read Mode"**

The Dual I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M7-0) =AXH, then the next Dual I/O Fast Read command (after CS# is raised and then lowered) does not require the BBH command code. The command sequence is shown in followed Figure11. If the "Continuous Read Mode" bits (M7-0) are any value other than AXH, the next command requires the first BBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M7-0) before issuing normal command.

### Figure 9. Dual I/O Fast Read Sequence Diagram (M7-0= 0XH or not AXH)

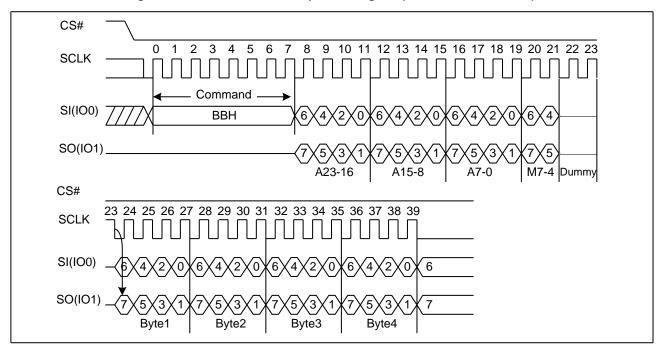
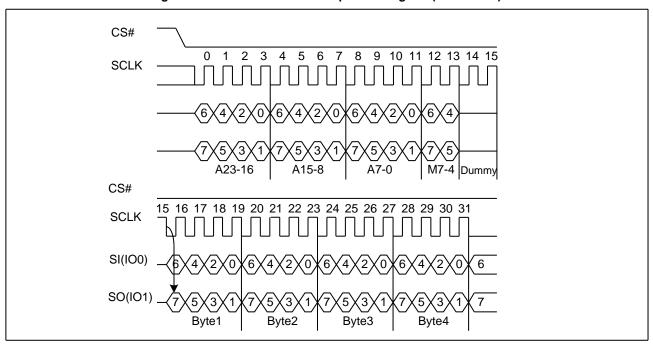


Figure 10. Dual I/O Fast Read Sequence Diagram (M7-0= AXH)



# 7.11. Quad I/O Fast Read (EBH)

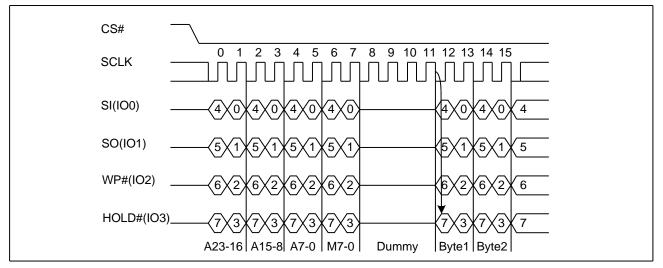
The Quad I/O Fast Read command is similar to the Dual I/O Fast Read command but with the capability to input the 3-byte address (A23-0) and a "Continuous Read Mode" byte and 4-dummy clock 4-bit per clock by IO0, IO1, IO2, IO3, each bit being latched in during the rising edge of SCLK, then the memory contents are shifted out 4-bit per clock cycle from IO0, IO1, IO2, IO3. The command sequence is shown in followed Figure 13. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Fast read command.

### Quad I/O Fast Read with "Continuous Read Mode"

The Quad I/O Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M7-0) =AXH, then the next Quad I/O Fast Read command (after CS# is raised and then lowered) does not require the EBH command code. The command sequence is shown in followed Figure 13. If the "Continuous Read Mode" bits (M7-0) are any value other than AXH, the next command requires the first EBH command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M7-0) before issuing normal command.

Figure 11. Quad I/O Fast Read Sequence Diagram (M7-0= 0XH or not AXH)

Figure 12. Quad I/O Fast Read Sequence Diagram (M7-0= AXH)



# 7.12. Quad I/O Word Fast Read (E7H)

The Quad I/O Word Fast Read command is similar to the Quad I/O Fast Read command except that the lowest address bit (A0) must equal 0 and only 2-dummy clock. The command sequence is shown in followed Figure 15. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. The Quad Enable bit (QE) of Status Register (S9) must be set to enable for the Quad I/O Word Fast read command.

### Quad I/O Word Fast Read with "Continuous Read Mode"

The Quad I/O Word Fast Read command can further reduce command overhead through setting the "Continuous Read Mode" bits (M7-0) after the input 3-byte address (A23-A0). If the "Continuous Read Mode" bits (M7-0) =AXH, then the next Quad I/O Word Fast Read command (after CS# is raised and then lowered) does not require the E7H command code. The command sequence is shown in followed Figure 15. If the "Continuous Read Mode" bits (M7-0) are any value other than AXH, the next command requires the first E7H command code, thus returning to normal operation. A "Continuous Read Mode" Reset command can be used to reset (M7-0) before issuing normal command.

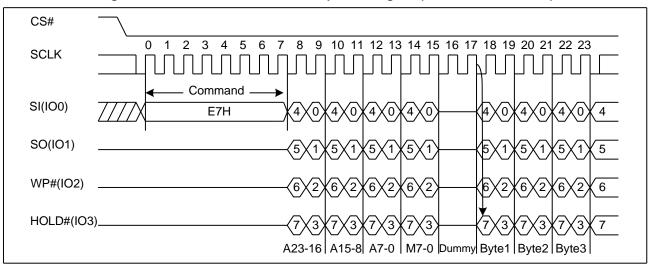
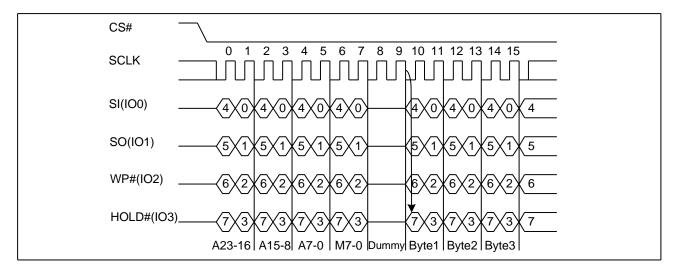


Figure 13. Quad I/O Word Fast Read Sequence Diagram (M7-0= 0XH or not AXH)

Figure 14. Quad I/O Word Fast Read Sequence Diagram (M7-0= AXH)



# 7.13. Page Program (PP) (02H)

The Page Program (PP) command is for programming the memory. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command.

The Page Program (PP) command is entered by driving CS# Low, followed by the command code, three address bytes and at least one data byte on SI. If the 8 least significant address bits (A7-A0) are not all zero, all transmitted data that goes beyond the end of the current page are programmed from the start address of the same page (from the address whose 8 least significant bits (A7-A0) are all zero). CS# must be driven low for the entire duration of the sequence. The Page Program command sequence: CS# goes low → sending Page Program command → 3-byte address on SI → at least 1 byte data on SI → CS# goes high. The command sequence is shown in Figure 18. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Page Program (PP) command is not executed.

As soon as CS# is driven high, the self-timed Page Program cycle (whose duration is t<sub>PP</sub>) is initiated. While the Page Program cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Page Program (PP) command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) is not executed.

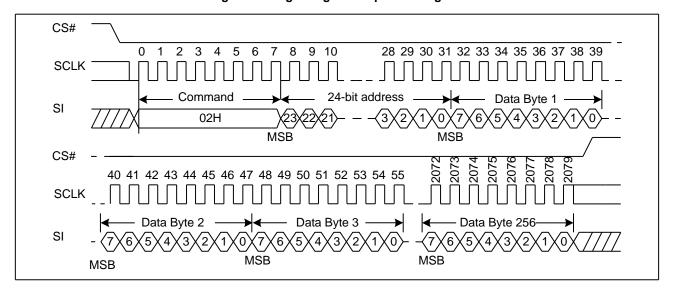


Figure 15. Page Program Sequence Diagram

# 7.14. Quad Page Program (32H)

The Quad Page Program command is for programming the memory using four pins: IO0, IO1, IO2, and IO3. To use Quad Page Program the Quad enable in status register Bit9 must be set (QE=1). A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Page Program command. The quad Page Program command is entered by driving CS# Low, followed by the command code (32H), three address bytes and at least one data byte on IO pins.

The command sequence is shown in Figure 19. If more than 256 bytes are sent to the device, previously latched data are discarded and the last 256 data bytes are guaranteed to be programmed correctly within the same page. If less than 256 data bytes are sent to device, they are correctly programmed at the requested addresses without having any effects on the other bytes of the same page. CS# must be driven high after the eighth bit of the last data byte has been latched in; otherwise the Quad Page Program (PP) command is not executed.

As soon as CS# is driven high, the self-timed Quad Page Program cycle (whose duration is tpp) is initiated. While the Quad Page Program cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Quad Page Program cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

A Quad Page Program command applied to a page which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) is not executed.

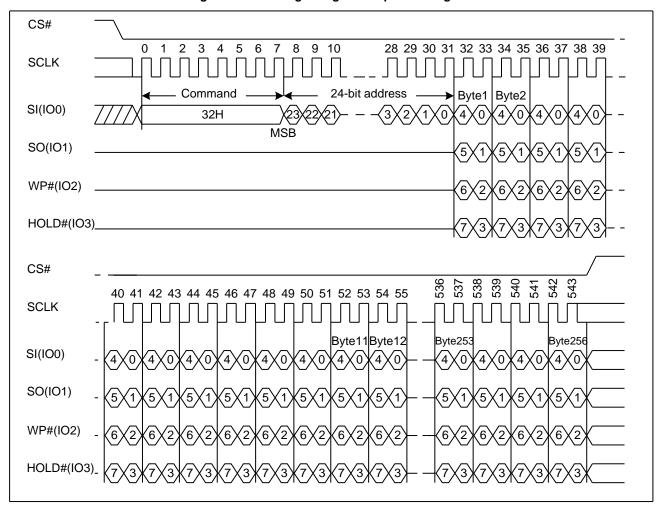


Figure 16.Quad Page Program Sequence Diagram

# 7.15. Sector Erase (SE) (20H)

The Sector Erase (SE) command is used to erase all the data of the chosen sector. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The Sector Erase (SE) command is entered by driving CS# low, followed by the command code, and 3-address byte on SI. Any address inside the sector is a valid address for the Sector Erase (SE) command. CS# must be driven low for the entire duration of the sequence.

The Sector Erase command sequence: CS# goes low  $\rightarrow$  sending Sector Erase command  $\rightarrow$  3-byte address on SI  $\rightarrow$  CS# goes high. The command sequence is shown in Figure 21. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the Sector Erase (SE) command is not executed. As soon as CS# is driven high, the self-timed Sector Erase cycle (whose duration is  $t_{SE}$ ) is initiated. While the Sector Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Sector Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A Sector Erase (SE) command applied to a sector which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) bit (see Table1&1a) is not executed.

SCLK 0 1 2 3 4 5 6 7 8 9 29 30 31

SCLK Command 24 Bits Address MSB

Figure 17. Sector Erase Sequence Diagram

# 7.16.32KB Block Erase (BE) (52H)

The 32KB Block Erase (BE) command is used to erase all the data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The 32KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and three address bytes on SI. Any address inside the block is a valid address for the 32KB Block Erase (BE) command. CS# must be driven low for the entire duration of the sequence.

The 32KB Block Erase command sequence: CS# goes low → sending 32KB Block Erase command → 3-byte address on SI → CS# goes high. The command sequence is shown in Figure 22. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 32KB Block Erase (BE) command is not executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is t<sub>BE</sub>) is initiated. While the Block Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 32KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) bits (see Table1&1a) is not executed.

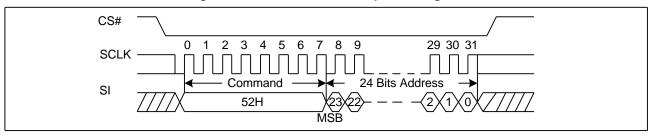


Figure 18. 32KB Block Erase Sequence Diagram

# 7.17.64KB Block Erase (BE) (D8H)

The 64KB Block Erase (BE) command is used to erase all the data of the chosen block. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit. The 64KB Block Erase (BE) command is entered by driving CS# low, followed by the command code, and three address bytes on SI. Any address inside the block is a valid address for the 64KB Block Erase (BE) command. CS# must be driven low for the entire duration of the sequence.

The 64KB Block Erase command sequence: CS# goes low → sending 64KB Block Erase command → 3-byte address on SI → CS# goes high. The command sequence is shown in Figure 23. CS# must be driven high after the eighth bit of the last address byte has been latched in; otherwise the 64KB Block Erase (BE) command is not executed. As soon as CS# is driven high, the self-timed Block Erase cycle (whose duration is t<sub>BE</sub>) is initiated. While the Block Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Block Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. A 64KB Block Erase (BE) command applied to a block which is protected by the Block Protect (BP4, BP3, BP2, BP1, and BP0) bits (see Table1&1a) is not executed.

SCLK 0 1 2 3 4 5 6 7 8 9 29 30 31

SCLK Command 24 Bits Address Address MSB

Figure 19. 64KB Block Erase Sequence Diagram

# 7.18. Chip Erase (CE) (60/C7H)

The Chip Erase (CE) command is used to erase all the data of the chip. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit .The Chip Erase (CE) command is entered by driving CS# Low, followed by the command code on Serial Data Input (SI). CS# must be driven Low for the entire duration of the sequence.

The Chip Erase command sequence: CS# goes low  $\rightarrow$  sending Chip Erase command  $\rightarrow$  CS# goes high. The command sequence is shown in Figure21. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Chip Erase command is not executed. As soon as CS# is driven high, the self-timed Chip Erase cycle (whose duration is  $t_{CE}$ ) is initiated. While the Chip Erase cycle is in progress, the Status Register may be read to check the value of the Write in Progress (WIP) bit. The Write in Progress (WIP) bit is 1 during the self-timed Chip Erase cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Chip Erase (CE) command is executed only if all Block Protect (BP2, BP1, and BP0) bits are 0. The Chip Erase (CE) command is ignored if one or more sectors are protected.

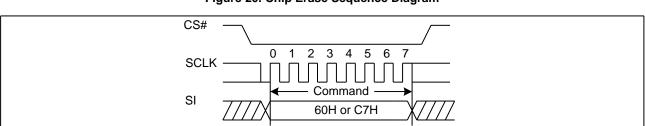


Figure 20. Chip Erase Sequence Diagram

# 7.19. Deep Power-Down (DP) (B9H)

Executing the Deep Power-Down (DP) command is the only way to put the device in the lowest consumption mode (the Deep Power-Down Mode). It can also be used as an extra software protection mechanism, while the device is not in active use, since in this mode, the device ignores all Write, Program and Erase commands. Driving CS# high deselects the device, and puts the device in the Standby Mode (if there is no internal cycle currently in progress). But this mode is not the Deep Power-Down Mode. The Deep Power-Down Mode can only be entered by executing the Deep Power-Down (DP) command. Once the device has entered the Deep Power-Down Mode, all commands are ignored except the Release from Deep Power-Down and Read Device ID (RDI) command. This releases the device from this mode. The Release from Deep Power-Down and Read Device ID (RDI) command also allows the Device ID of the device to be output on SO.

The Deep Power-Down Mode automatically stops at Power-Down, and the device always Power-Up in the Standby Mode. The Deep Power-Down (DP) command is entered by driving CS# low, followed by the command code on SI. CS# must be driven low for the entire duration of the sequence.

The Deep Power-Down command sequence: CS# goes low  $\rightarrow$  sending Deep Power-Down command  $\rightarrow$  CS# goes high. The command sequence is shown in Figure 22. CS# must be driven high after the eighth bit of the command code has been latched in; otherwise the Deep Power-Down (DP) command is not executed. As soon as CS# is driven high, it requires a delay of  $t_{DP}$  before the supply current is reduced to  $t_{CC2}$  and the Deep Power-Down Mode is entered. Any Deep Power-Down (DP) command, while an Erase, Program or Write cycle is in progress, is rejected without having any effects on the cycle that is in progress.

CS#

SCLK

0 1 2 3 4 5 6 7

SCLK

Command

Stand-by mode Deep Power-down mode

B9H

Figure 21. Deep Power-Down Sequence Diagram

# 7.20. Release from Deep Power-Down or High Performance Mode and Read Device ID (RDI) (ABH)

The Release from Power-Down or High Performance Mode / Device ID command is a multi-purpose command. It can be used to release the device from the Power-Down state or High Performance Mode or obtain the devices electronic identification (ID) number.

To release the device from the Power-Down state or High Performance Mode, the command is issued by driving the CS# pin low, shifting the instruction code "ABH" and driving CS# high as shown in Figure 26. Release from Power-Down will take the time duration of trest (See AC Characteristics) before the device will resume normal operation and other command are accepted. The CS# pin must remain high during the trest time duration.

When used only to obtain the Device ID while not in the Power-Down state, the command is initiated by driving the CS# pin low and shifting the instruction code "ABH" followed by 3-dummy byte. The Device ID bits are then shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 27. The Device ID value is listed in Manufacturer and Device Identification table. The Device ID can be read continuously. The command is completed by driving CS# high.

When used to release the device from the Power-Down state and obtain the Device ID, the command is the same as previously described, and shown in Figure27, except that after CS# is driven high it must remain high for a time duration of t<sub>RES2</sub> (See AC Characteristics). After this time duration the device will resume normal operation and other command will be accepted. If the Release from Power-Down / Device ID command is issued while an Erase, Program or Write cycle is in process (when WIP equal 1) the command is ignored and will not have any effects on the current cycle.

Figure 22. Release Power-Down Sequence or High Performance Mode Sequence Diagram

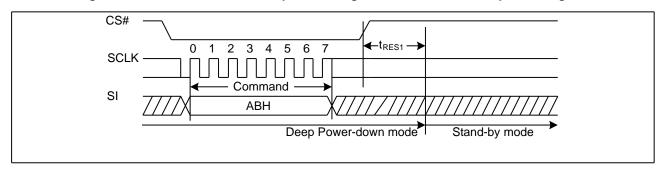
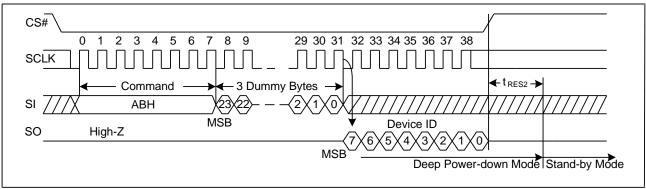


Figure 23. Release Power-Down/Read Device ID Sequence Diagram



# 7.21. Read Manufacture ID/ Device ID (REMS) (90H)

The Read Manufacturer/Device ID command is an alternative to the Release from Power-Down / Device ID command that provides both the JEDEC assigned Manufacturer ID and the specific Device ID.

The command is initiated by driving the CS# pin low and shifting the command code "90H" followed by a 24-bit address (A23-A0) of 000000H. After which, the Manufacturer ID and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in Figure 28. If the 24-bit address is initially set to 000001H, the Device ID will be read first.

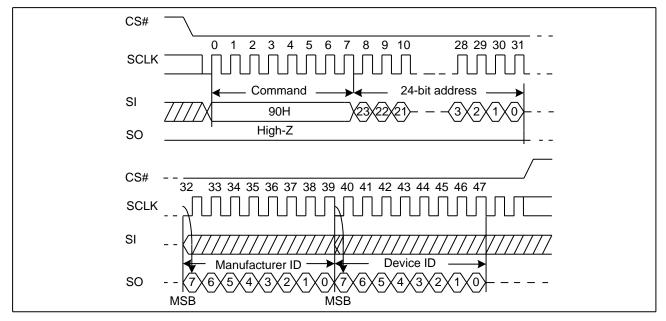


Figure 24. Read Manufacture ID/ Device ID Sequence Diagram

# 7.22. Read Identification (RDID) (9FH)

The Read Identification (RDID) command allows the 8-bit manufacturer identification to be read, followed by two bytes of device identification. The device identification indicates the memory type in the first byte, and the memory capacity of the device in the second byte. The Read Identification (RDID) command while an Erase or Program cycle is in progress is not decoded, and has no effect on the cycle that is in progress. The Read Identification (RDID) command should not be issued while the device is in Deep Power-Down Mode.

The device is first selected by driving CS# to low. Then, the 8-bit command code for the command is shifted in. This is followed by the 24-bit device identification, stored in the memory, being shifted out on Serial Data Output, each bit being shifted out during the falling edge of Serial Clock. The command sequence is shown in Figure 31. The Read Identification (RDID) command is terminated by driving CS# to high at any time during data output. When CS# is driven high, the device is put in the Standby Mode. Once in the Standby Mode, the device waits to be selected, so that it can receive, decode and execute commands.

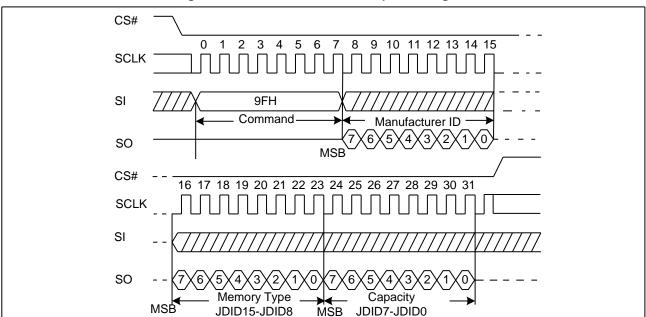


Figure 25. Read Identification ID Sequence Diagram

# 7.23. High Performance Mode (HPM) (A3H)

The High Performance Mode (HPM) command must be executed prior to Dual or Quad I/O commands when operating at high frequencies (see  $f_R$  and  $f_{C1}$  in AC Electrical Characteristics). This command allows pre-charging of internal charge pumps so the voltages required for accessing the flash memory array are readily available. The command sequence: CS# goes low $\rightarrow$ Sending A3H command $\rightarrow$  Sending 3-dummy byte $\rightarrow$ CS# goes high. See Figure 32. After the HPM command is executed, the device will maintain a slightly higher standby current (Icc8) than standard SPI operation. The Release from Power-Down or HPM command (ABH) can be used to return to standard SPI standby current (Icc1). In addition, Power-Down command (B9H) will also release the device from HPM mode back to standard SPI standby state.

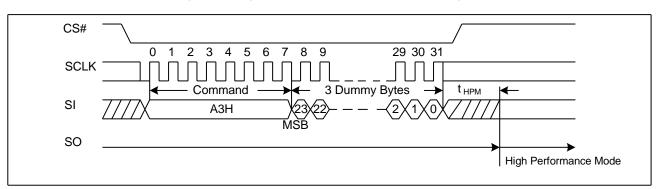


Figure 26. High Performance Mode Sequence Diagram

# 7.24. Continuous Read Mode Reset (CRMR) (FFH)

The Dual/Quad I/O Fast Read operations, "Continuous Read Mode" bits (M7-0) are implemented to further reduce command overhead. By setting the (M7-0) to AXH, the next Dual/Quad I/O Fast Read operations do not require the BBH/EBH/E7H command code.

Because the GD25Q16C has no hardware reset pin, so if Continuous Read Mode bits are set to "AXH", the GD25Q16C will not recognize any standard SPI commands. So Continuous Read Mode Reset command will release the Continuous Read Mode from the "AXH" state and allow standard SPI command to be recognized. The command sequence is show in Figure 28.

←Mode Bit Reset for Quad/Dual I/O→ CS# 2 3 4 5 6 **SCLK** SI(IO0) **FFH** SO(IO1) Don't Care WP#(IO2) Don't Care HOLD#(IO3)  $\sqrt{\phantom{a}}$ Don't Care

Figure 27. Continuous Read Mode Reset Sequence Diagram

# 7.25. Read Unique ID (4BH)

The Read Unique ID command accesses a factory-set read-only 128bit number that is unique to each GD25Q16C device. The Unique ID can be used in conjunction with user software methods to help prevent copying or cloning of a system. The Read Unique ID command sequence: CS# goes low → sending Read Unique ID command → Dummy Byte1 → Dummy Byte2 → Dummy Byte3 → Dummy Byte4→128bit Unique ID Out → CS# goes high. The command sequence is show below.

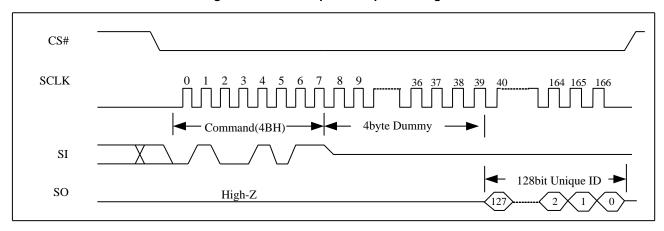


Figure 28. Read Unique ID Sequence Diagram

# 7.26. Program/Erase Suspend (PES) (75H)

The Program/Erase Suspend command "75H", allows the system to interrupt a page program or sector/block erase operation and then read data from any other sector or block. The Write Status Register command (01H) and Erase/Program Security Registers command (44H, 42H) and Erase commands (20H, 52H, D8H, C7H, 60H) and Page Program command (02H / 32H) are not allowed during Program/Erase suspend. Program/Erase Suspend is valid only during the page program or sector/block erase operation. A maximum of time of "tsus" (See AC Characteristics) is required to suspend the program/erase operation.

The Program/Erase Suspend command will be accepted by the device only if the SUS bit in the Status Register equal to 0 and WIP bit equal to 1 while a Page Program or a Sector or Block Erase operation is on-going. If the SUS bit equal to 1 or WIP bit equal to 0, the Suspend command will be ignored by the device. The WIP bit will be cleared from 1 to 0 within "tsus" and the SUS bit will be set from 0 to 1 immediately after Program/Erase Suspend. A power-off during the suspend period will reset the device and release the suspend state. The command sequence is show in Figure 34.

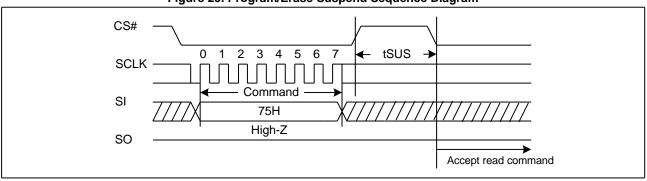


Figure 29. Program/Erase Suspend Sequence Diagram

# 7.27. Program/Erase Resume (PER) (7AH)

The Program/Erase Resume command must be written to resume the program or sector/block erase operation after a Program/Erase Suspend command. The Program/Erase command will be accepted by the device only if the SUS bit equal to 1 and the WIP bit equal to 0. After issued the SUS bit in the status register will be cleared from 1 to 0 immediately, the WIP bit will be set from 0 to 1 within 200ns and the Sector or Block will complete the erase operation or the page will complete the program operation. The Program/Erase Resume command will be ignored unless a Program/Erase Suspend is active. The command sequence is show in Figure 35.

SCLK 0 1 2 3 4 5 6 7

SCLK Command Command SI 7AH

SO Resume Erase/Program

Figure 30. Program/Erase Resume Sequence Diagram

# 7.28. Erase Security Registers (44H)

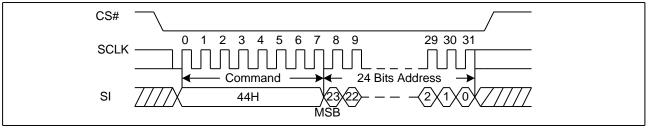
The GD25Q16C provides four 256-byte Security Registers which can be erased and programmed individually. These registers may be used by the system manufacturers to store security and other important information separately from the main memory array.

The Erase Security Registers command is similar to Sector/Block Erase command. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit.

The Erase Security Registers command sequence: CS# goes low  $\rightarrow$  sending Erase Security Registers command  $\rightarrow$  CS# goes high. The command sequence is shown in Figure31. CS# must be driven high after the eighth bit of the command code has been latched in, otherwise the Erase Security Registers command is not executed. As soon as CS# is driven high, the self-timed Erase Security Registers cycle (whose duration is  $t_{SE}$ ) is initiated. While the Erase Security Registers cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Erase Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset. The Security Registers Lock Bit (LB) in the Status Register can be used to OTP protect the security registers. Once the LB bit is set to 1, the Security Registers will be permanently locked; the Erase Security Registers command will be ignored.

Address	A23-A16	A15-A10	A9-A0
Security Registers	00000000	000000	Don't Care

Figure 31. Erase Security Registers command Sequence Diagram



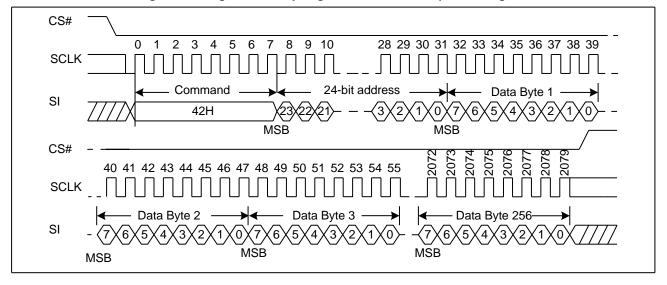
# 7.29. Program Security Registers (42H)

The Program Security Registers command is similar to the Page Program command. It allows from 1 to 256 bytes Security Registers data to be programmed. A Write Enable (WREN) command must previously have been executed to set the Write Enable Latch (WEL) bit before sending the Program Security Registers command. The Program Security Registers command is entered by driving CS# Low, followed by the command code (42H), three address bytes and at least one data byte on SI. As soon as CS# is driven high, the self-timed Program Security Registers cycle (whose duration is t<sub>PP</sub>) is initiated. While the Program Security Registers cycle is in progress, the Status Register may be read to check the value of the Write In Progress (WIP) bit. The Write In Progress (WIP) bit is 1 during the self-timed Program Security Registers cycle, and is 0 when it is completed. At some unspecified time before the cycle is completed, the Write Enable Latch (WEL) bit is reset.

If the Security Registers Lock Bit (LB) is set to 1, the Security Registers will be permanently locked. Program Security Registers command will be ignored.

Address	A23-A16	A15-A8	A7-A0
Security Registers 0	00H	00H	Byte Address
Security Registers 1	00H	01H	Byte Address
Security Registers 2	00H	02H	Byte Address
Security Registers 3	00H	03H	Byte Address

Figure 32. Program Security Registers command Sequence Diagram

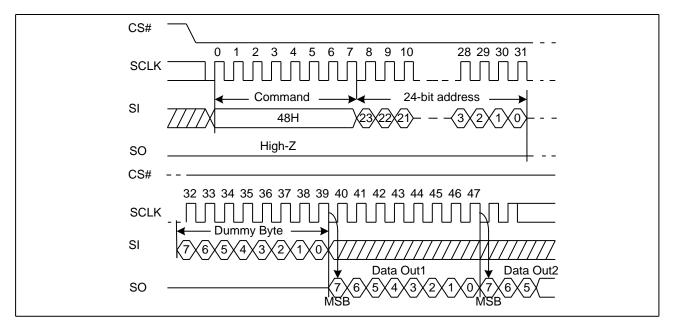


# 7.30. Read Security Registers (48H)

The Read Security Registers command is similar to Fast Read command. The command is followed by a 3-byte address (A23-A0) and a dummy byte, each bit being latched-in during the rising edge of SCLK. Then the memory content, at that address, is shifted out on SO, each bit being shifted out, at a Max frequency fc, during the falling edge of SCLK. The first byte addressed can be at any location. The address is automatically incremented to the next higher address after each byte of data is shifted out. Once the A9-A0 address reaches the last byte of the register (Byte 3FFH), it will reset to 000H, the command is completed by driving CS# high.

Address	A23-A16	A15-A10	A9-A0
Security Registers	0000000	000000	Address

Figure 33. Read Security Registers command Sequence Diagram

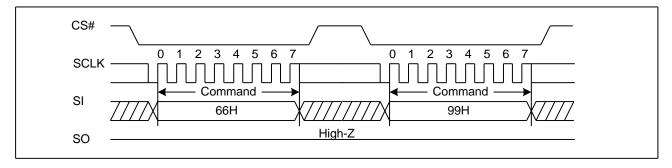


# 7.31. Enable Reset (66H) and Reset (99H)

If the Reset command is accepted, any on-going internal operation will be terminated and the device will return to its default power-on state and lose all the current volatile settings, such as Volatile Status Register bits, Write Enable Latch status (WEL), Program/Erase Suspend status, Read Parameter setting (P7-P0), Continuous Read Mode bit setting (M7-M0) and Wrap Bit Setting (W6-W4).

The "Reset (99H)" command sequence as follow: CS# goes low  $\rightarrow$  Sending Enable Reset command  $\rightarrow$  CS# goes high. Once the Reset command is accepted by the device, the device will take approximately  $t_{RST}$  =60us to reset. During this period, no command will be accepted. Data corruption may happen if there is an on-going or suspended internal Erase or Program operation when Reset command sequence is accepted by the device. It is recommended to check the BUSY bit and the SUS bit in Status Register before issuing the Reset command sequence.

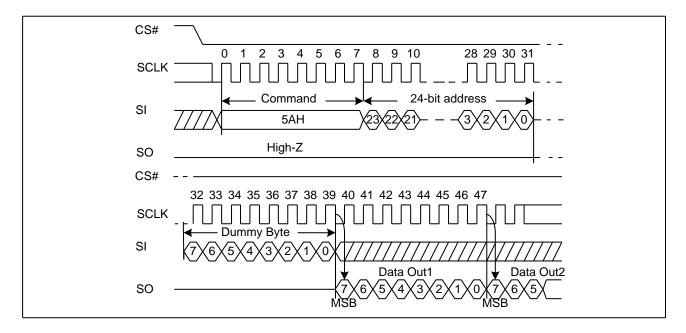
Figure 34. Enable Reset and Reset command Sequence Diagram



### 7.32. Read Serial Flash Discoverable Parameter (5AH)

The Serial Flash Discoverable Parameter (SFDP) standard provides a consistent method of describing the functional and feature capabilities of serial flash devices in a standard set of internal parameter tables. These parameter tables can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. The concept is similar to the one found in the Introduction of JEDEC Standard, JESD68 on CFI. SFDP is a standard of JEDEC Standard No.216.

Figure 35. Read Serial Flash Discoverable Parameter command Sequence Diagram



**GD25Q16C** 

### Table3. Signature and Parameter Identification Data Values

Description	Comment	Add(H)	DW Add	Data	Data
		(Byte)	(Bit)		
SFDP Signature	Fixed:50444653H	00H	07:00	53H	53H
		01H	15:08	46H	46H
		02H	23:16	44H	44H
		03H	31:24	50H	50H
SFDP Minor Revision Number	Start from 00H	04H	07:00	00H	00H
SFDP Major Revision Number	Start from 01H	05H	15:08	01H	01H
Number of Parameters Headers	Start from 00H	06H	23:16	01H	01H
Unused	Contains 0xFFH and can never be	07H	31:24	FFH	FFH
	changed				
ID number (JEDEC)	00H: It indicates a JEDEC specified	08H	07:00	00H	00H
	header				
Parameter Table Minor Revision	Start from 0x00H	09H	15:08	00H	00H
Number					
Parameter Table Major Revision	Start from 0x01H	0AH	23:16	01H	01H
Number					
Parameter Table Length	How many DWORDs in the	0BH	31:24	09H	09H
(in double word)	Parameter table				
Parameter Table Pointer (PTP)	First address of JEDEC Flash	0CH	07:00	30H	30H
	Parameter table	0DH	15:08	00H	00H
		0EH	23:16	00H	00H
Unused	Contains 0xFFH and can never be changed	0FH	31:24	FFH	FFH
ID Number	It is indicates GigaDevice	10H	07:00	C8H	C8H
(GigaDevice Manufacturer ID)	manufacturer ID				
Parameter Table Minor Revision	Start from 0x00H	11H	15:08	00H	00H
Number					
Parameter Table Major Revision	Start from 0x01H	12H	23:16	01H	01H
Number					
Parameter Table Length	How many DWORDs in the	13H	31:24	03H	03H
(in double word)	Parameter table				
Parameter Table Pointer (PTP)	First address of GigaDevice Flash	14H	07:00	60H	60H
	Parameter table	15H	15:08	00H	00H
		16H	23:16	00H	00H
Unused	Contains 0xFFH and can never be	17H	31:24	FFH	FFH
	changed				

**GD25Q16C** 

### Table4. Parameter Table (0): JEDEC Flash Parameter Tables

Description	Comment	Add(H)	DW Add	Data	Data
		(Byte)	(Bit)		
	00: Reserved; 01: 4KB erase;				
Block/Sector Erase Size	10: Reserved;		01:00	01b	
	11: not support 4KB erase				
Write Granularity	0: 1Byte, 1: 64Byte or larger		02	1b	
Write Enable Instruction	0: Nonvolatile status bit				
Requested for Writing to Volatile	1: Volatile status bit		03	0b	
Status Registers	(BP status register bit)	30H			E5H
	3011			2011	
Write Enable Opcode Select for	1: Use 06H Opcode,				
Writing to Volatile Status	Note: If target flash status register is		04	0b	
Registers	Nonvolatile, then bits 3 and 4 must				
	be set to 00b.				
Unused	Contains 111b and can never be		07:05	111b	
Ollused	changed		07.03	1110	
4KB Erase Opcode		31H	15:08	20H	20H
(1-1-2) Fast Read	0=Not support, 1=Support		16	1b	
Address Bytes Number used in	00: 3Byte only, 01: 3 or 4Byte,		18:17	00b	
addressing flash array	10: 4Byte only, 11: Reserved		10.17	dob	
Double Transfer Rate (DTR)	0=Not support, 1=Support		19	0b	
clocking	U=NOT Support, 1=Support	32H	19	OD	F1H
(1-2-2) Fast Read	0=Not support, 1=Support		20	1b	
(1-4-4) Fast Read	0=Not support, 1=Support		21	1b	
(1-1-4) Fast Read	0=Not support, 1=Support		22	1b	
Unused			23	1b	
Unused		33H	31:24	FFH	FFH
Flash Memory Density		37H:34H	31:00	00FFFF	FFH
(1-4-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy		04:00	00100b	
states	Clocks) not support	2011	04.00	001000	4411
(1-4-4) Fast Read Number of	000h:Mada Pita not augnort	38H	07:05	010b	44H
Mode Bits	000b:Mode Bits not support		07.05	0100	
(1-4-4) Fast Read Opcode		39H	15:08	EBH	EBH
(1-1-4) Fast Read Number of Wait	0 0000b: Wait states (Dummy		20.16	01000h	
states	Clocks) not support	241	20:16	01000b	0011
(1-1-4) Fast Read Number of	000h:Mada Bita nat aurant	3AH	22.24	0004	08H
Mode Bits not support			23:21	000b	
(1-1-4) Fast Read Opcode		3BH	31:24	6BH	6BH



# 3.3V Uniform Sector Gigabevice Dual and Quad Serial Flash

# GD25Q16C

Description	Gigabevice Buai alia Co						
States   Clocks   not support   Octobro   Oc	Description	Comment			Data	Data	
(1-1-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         3DH         15:08         3BH         3BH           (1-1-2) Fast Read Opcode         0 000b: Wait states (Dummy of Wait states)         20:16         00010b         2BH           (1-2-2) Fast Read Number of Mode Bits         0 000b: Mode Bits not support         3FH         31:24         BBH         BBH           (1-2-2) Fast Read Opcode         9-not support         1-support         4BH         31:24         BBH         BBH           (2-2-2) Fast Read         0-not support         1-support         4BH         4BH         BBH         BBH           (2-2-2) Fast Read         0-not support         1-support         4BH         4BH         BBH         BBH           (2-2-2) Fast Read         0-not support         1-support         4BH         31:00         0b         0b           Unused         0-not support         1-support         4BH         31:00         0xFFH         0xFFH           Unused         0-not support         4BH         31:04         0xFFH         0xFFH         0xFFH           Unused         0-not support         4BH         15:00         0xFFH         0xFFH           Unused         0-2-2-1 Sat Read Number         000b: Mait states (Du	` '	, , ,		04:00	01000b		
(1-2-2) Fast Read Number of Wait states         0 00000b: Wait states (Dummy of Wait states)         3EH         20:16         00010b         42H           (1-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         3FH         31:24         BBH         BBH           (1-2-2) Fast Read Opcode         3FH         31:24         BBH         BBH           (2-2-2) Fast Read         0=not support         1=support         00         0b           Unused         0=not support         1=support         00         0b           Unused         0=not support         1=support         00         0b           Unused         0=not support         43H:41H         31:08         0xFFH         0xFFH           Unused         0=not support         45H:44H         15:00         0xFFH         0xFFH           Unused         0=not support         45H:44H         15:00         0xFFH         0xFFH           (2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         46H         31:24         FFH         FFH           Unused         47H         31:24         FFH         0xFFH         0xFFH           Unused         49H:48H         15:00         0xFFH         0xFFH           Unused	,	000b: Mode Bits not support	- 3CH	07:05	000b	08H  3BH  42H  BBH  EEH  0xFFH  0xFFH  0xFFH  0xFFH  0xFFH  10H  10H  10H  10H  10H  10H  10H	
of Wait states         Clocks) not support         3EH         20:16         00010b         42H           (1-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         3FH         31:24         BBH         BBH           (2-2-2) Fast Read Opcode         0=not support         1=support         40H         37:24         BBH         BBH           (2-2-2) Fast Read         0=not support         1=support         40H         00         00         00           (4-4-4) Fast Read         0=not support         1=support         40H         03:01         111b         00         00           Unused         0=not support         1=support         40H         04         0b         00	(1-1-2) Fast Read Opcode		3DH	15:08	3BH	3BH	
(1-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         23:21         010b         BBH         BBH         BBH         C2-2-2) Fast Read Opcode         3FH         31:24         BBH         BBH         BBH         C2-2-2) Fast Read         0=not support         1=support         40H         03:01         111b         111b         EEH         64-4-4) Fast Read         0=not support         1=support         000:00         00 00b         00 00 00 00b	` '	, , ,	3EH	20:16	00010b	42H	
(2-2-2) Fast Read         0 = not support         1 = support         40H         0 = 00 00 00 00 00 00 00 00 00 00 00 00	, ,	000b: Mode Bits not support	OLI I	23:21	010b		
Unused         0 ont support         1 support         40H         03:01         111b         EEH           (4-4-4) Fast Read         0 ont support         1 support         04         0b         07:05         111b           Unused         4 3H:4H         31:08         0xFFH         0xFFH           Unused         4 5H:44H         15:00         0xFFH         0xFFH           (2-2-2) Fast Read Number of Wait states         0000b: Wait states (Dummy of Mode Bits not support         46H         20:16         00000b           (2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         47H         31:24         FFH         FFH           Unused         47H         31:24         FFH         0xFFH           Unused         47H         31:24         FFH         0xFFH           Unused         47H         31:24         FFH         0xFFH           Unused         49H:48H         15:00         0xFFH         0xFFH           Unused         49H:48H         15:00         0xFFH         0xFFH           Unused         49H:48H         15:00         0xFFH         0xFH           Unused         49H:48H         15:00         0xFH         0xFH           44-4.9	(1-2-2) Fast Read Opcode		3FH	31:24	BBH	BBH	
(4-4-4) Fast Read         0=not support         1=support         40H         04         0b         0ch         0b         0ch         0ch         0b         0ch         0	(2-2-2) Fast Read	0=not support 1=support		00	0b		
C4-4-4  Fast Read   O=not support   1=support   1=su	Unused		4011	03:01	111b	FFU	
Unused         43H:41H         31:08         0xFFH         0xFFH           Unused         45H:44H         15:00         0xFFH         0xFFH           (2-2-2) Fast Read Number of Wait states         0 0000b: Wait states (Dummy Clocks) not support         20:16         00000b           (2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         46H         23:21         000b           (2-2-2) Fast Read Opcode         47H         31:24         FFH         FFH           Unused         49H:48H         15:00         0xFFH         0xFFH           (4-4-4) Fast Read Number of Wait states (Dummy Clocks) not support         20:16         00000b         0xFFH           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         4AH         31:24         FFH         FFH           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 3 size         Sector/block size=2^N bytes	(4-4-4) Fast Read	0=not support 1=support	40H	04	EEH		
Unused         45H:44H         15:00         0xFFH         0xFFH           (2-2-2) Fast Read Number of Wait states         0 0000b: Wait states (Dummy Clocks) not support         20:16         00000b         00000b           (2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         46H         23:21         000b         00H           (2-2-2) Fast Read Opcode         47H         31:24         FFH         FFH           Unused         49H:48H         15:00         0xFFH         0xFFH           (4-4-4) Fast Read Number of Wait states (Dummy Clocks) not support         20:16         00000b         0000b           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         4AH         20:16         00000b           (4-4-4) Fast Read Opcode         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 3 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Typ	Unused			07:05	111b		
(2-2-2) Fast Read Number of Wait states         0 0000b: Wait states (Dummy Clocks) not support         46H         20:16         00000b         00H           (2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         47H         31:24         FFH         FFH           Unused         49H:48H         15:00         0xFFH         0xFFH           (4-4-4) Fast Read Number of Wait states (Dummy Clocks) not support         20:16         00000b         00000b           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         20:16         00000b         0000b           (4-4-4) Fast Read Opcode         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 1 erase Opcode         4DH         15:08         20H         20H           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 3 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Type 3 erase Opcode         51H         15:08         D8H         D8H <td>Unused</td> <td></td> <td>43H:41H</td> <td>31:08</td> <td>0xFFH</td> <td>0xFFH</td>	Unused		43H:41H	31:08	0xFFH	0xFFH	
of Wait states         Clocks) not support         20:16         00000b           (2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         23:21         000b           (2-2-2) Fast Read Opcode         47H         31:24         FFH         FFH           Unused         49H:48H         15:00         0xFFH         0xFFH           (4-4-4) Fast Read Number of Wait states (Dummy Clocks) not support         20:16         00000b         00000b           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         23:21         000b         00H           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 1 erase Opcode         4DH         15:08         20H         20H           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 2 erase Opcode         4FH         31:24         52H         52H         52H           Sector Type 3 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Type 4 Size         Sector/block size=2^N bytes 0x00b: this sector type don't ex	Unused		45H:44H	15:00	0xFFH	0xFFH	
(2-2-2) Fast Read Number of Mode Bits         000b: Mode Bits not support         23:21         000b           (2-2-2) Fast Read Opcode         47H         31:24         FFH         FFH           Unused         49H:48H         15:00         0xFFH         0xFFH           (4-4-4) Fast Read Number of Wait states         0 0000b: Wait states (Dummy Clocks) not support         20:16         00000b         00000b           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         4AH         23:21         000b           (4-4-4) Fast Read Opcode         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 1 erase Opcode         4DH         15:08         20H         20H           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 2 erase Opcode         4FH         31:24         52H         52H         52H           Sector Type 3 size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Type 4 Size         Sector/blo	,	, , ,		20:16	00000b		
Unused         49H:48H         15:00         0xFFH         0xFFH           (4-4-4) Fast Read Number of Wait states         0 0000b: Wait states (Dummy Clocks) not support         20:16         00000b         00000b           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         23:21         000b         00H           (4-4-4) Fast Read Opcode         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 1 erase Opcode         4DH         15:08         20H         20H           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 2 erase Opcode         4FH         31:24         52H         52H         52H           Sector Type 3 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Type 4 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         52H         23:16         00H         00H		000b: Mode Bits not support	- 46H	23:21	000b	00H	
(4-4-4) Fast Read Number of Wait states         0 0000b: Wait states (Dummy Clocks) not support         4AH         20:16         00000b         00H           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         4BH         31:24         FFH         FFH           (4-4-4) Fast Read Opcode         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 1 erase Opcode         4DH         15:08         20H         20H           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 2 erase Opcode         4FH         31:24         52H         52H         52H           Sector Type 3 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Type 3 erase Opcode         51H         15:08         D8H         D8H           Sector Type 4 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         52H         23:16         00H         00H	(2-2-2) Fast Read Opcode		47H	31:24	FFH	FFH	
states         Clocks) not support         4AH         20:16         00000b         00H           (4-4-4) Fast Read Number of Mode Bits         000b: Mode Bits not support         23:21         000b         00h           (4-4-4) Fast Read Opcode         4BH         31:24         FFH         FFH           Sector Type 1 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4CH         07:00         0CH         0CH           Sector Type 1 erase Opcode         4DH         15:08         20H         20H           Sector Type 2 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         4EH         23:16         0FH         0FH           Sector Type 2 erase Opcode         4FH         31:24         52H         52H           Sector Type 3 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         50H         07:00         10H         10H           Sector Type 3 erase Opcode         51H         15:08         D8H         D8H           Sector Type 4 Size         Sector/block size=2^N bytes 0x00b: this sector type don't exist         52H         23:16         00H         00H	Unused		49H:48H	15:00	0xFFH	0xFFH	
(4-4-4) Fast Read Number of Mode Bits000b: Mode Bits not support23:21000b(4-4-4) Fast Read Opcode4BH31:24FFHFFHSector Type 1 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist4CH07:000CH0CHSector Type 1 erase Opcode4DH15:0820H20HSector Type 2 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist4EH23:160FH0FHSector Type 2 erase Opcode4FH31:2452H52HSector Type 3 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist50H07:0010H10HSector Type 3 erase Opcode51H15:08D8HD8HSector Type 4 SizeSector/block size=2^N bytes 0x00b: this sector type don't exist52H23:1600H00H		, ,	400	20:16	00000b	00H	
Sector Type 1 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  4CH 07:00 0CH 0CH  Sector Type 1 erase Opcode  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 2 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 erase Opcode  Sector Type 3 erase Opcode  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size	, ,	000b: Mode Bits not support	4011	23:21	000b	0011	
Sector Type 1 Size  Ox00b: this sector type don't exist  Sector Type 1 erase Opcode  Sector Type 2 Size  Sector/block size=2^N bytes Ox00b: this sector type don't exist  Sector Type 2 erase Opcode  Sector/block size=2^N bytes Ox00b: this sector type don't exist  Sector Type 3 Size  Sector/block size=2^N bytes Ox00b: this sector type don't exist  Sector Type 3 erase Opcode  Sector Type 3 erase Opcode  Sector/block size=2^N bytes Ox00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes Ox00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes Ox00b: this sector type don't exist  Sector Type 4 Size  Sector Type 4 Size  OX00b: this sector type don't exist  Sector Type 4 Size	(4-4-4) Fast Read Opcode		4BH	31:24	FFH	FFH	
Sector Type 2 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 2 erase Opcode  Sector Type 3 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 erase Opcode  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist	Sector Type 1 Size	,	4CH	07:00	0CH	0CH	
Sector Type 2 Size  0x00b: this sector type don't exist  4EH  23:16  0FH  0FH  Sector Type 2 erase Opcode  4FH  31:24  52H  52H  Sector Type 3 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 erase Opcode  Sector/block size=2^N bytes 0x00b: this sector type don't exist  50H  07:00  10H  10H  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  52H  23:16  0FH  0FH  0FH  0FH  52H  52H  52H  52H  60H  60H	Sector Type 1 erase Opcode		4DH	15:08	20H	20H	
Sector Type 3 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 3 erase Opcode  Sector/block size=2^N bytes 0x00b: this sector type don't exist  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  50H 07:00 10H 10H 10H  D8H  Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist	Sector Type 2 Size	,	4EH	23:16	0FH	0FH	
Sector Type 3 Size  0x00b: this sector type don't exist  50H  07:00  10H  10H  Sector Type 3 erase Opcode  51H  15:08  D8H  D8H  Sector Type 4 Size  0x00b: this sector type don't exist  52H  23:16  00H  00H	Sector Type 2 erase Opcode		4FH	31:24	52H	52H	
Sector Type 4 Size  Sector/block size=2^N bytes 0x00b: this sector type don't exist  52H 23:16 00H 00H	Sector Type 3 Size	,	50H	07:00	10H	10H	
Sector Type 4 Size 0x00b: this sector type don't exist 52H 23:16 00H 00H	Sector Type 3 erase Opcode		51H	15:08	D8H	D8H	
Sector Type 4 erase Opcode 53H 31:24 FFH FFH	Sector Type 4 Size	-	52H	23:16	00H	00H	
0011   01.27   1111   1111	Sector Type 4 erase Opcode		53H	31:24	FFH	FFH	

# **GD25Q16C**

## Table5. Parameter Table (1): GigaDevice Flash Parameter Tables

Description	Comment	Add(H) (Byte)	DW Add (Bit)	Data	Data 3600H 2700H
Vcc Supply Maximum Voltage	2000H=2.000V 2700H=2.700V 3600H=3.600V	61H:60H	15:00	3600H	3600H
Vcc Supply Minimum Voltage	1650H=1.650V 2250H=2.250V 2300H=2.300V 2700H=2.700V	63H:62H	31:16	2700H	2700H
HW Reset# pin	0=not support 1=support		00	0b	
HW Hold# pin	0=not support 1=support		01	1b	
Deep Power Down Mode	0=not support 1=support	-	02	1b	
SW Reset	0=not support 1=support		03	1b	
SW Reset Opcode	Should be issue Reset Enable(66H) before Reset cmd.	65H:64H	11:04	99H	799EH
Program Suspend/Resume	0=not support 1=support		12	1b	
Erase Suspend/Resume	0=not support 1=support		13	1b	
Unused			14	1b	_
Wrap-Around Read mode	0=not support 1=support		15	0b	
Wrap-Around Read mode Opcode		66H	23:16	FFH	FFH
Wrap-Around Read data length	08H:support 8B wrap-around read 16H:8B&16B 32H:8B&16B&32B 64H:8B&16B&32B&64B	67H	31:24	64H	64H
Individual block lock	0=not support 1=support		00	0b	
Individual block lock bit (Volatile/Nonvolatile)	0=Volatile 1=Nonvolatile		01	0b	
Individual block lock Opcode		-	09:02	FFH	
Individual block lock Volatile protect bit default protect status  0=protect 1=unprotect		6BH:68H	10	0b	EBFCH
Secured OTP	0=not support 1=support		11	1b	
Read Lock	0=not support 1=support		12	0b	
Permanent Lock	0=not support 1=support		13	1b	
Unused		1	15:14	11b	
Unused			31:16	FFFFH	FFFFH

### 8. ELECTRICAL CHARACTERISTICS

### 8.1. POWER-ON TIMING

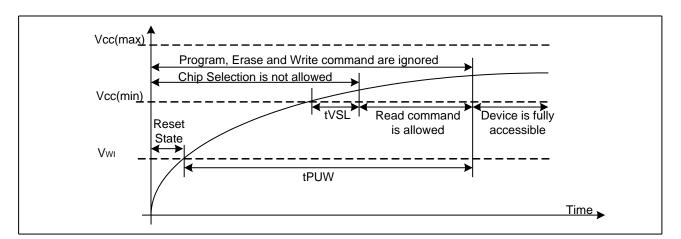


Table6. Power-Up Timing and Write Inhibit Threshold

Symbol	Parameter	Min	Тур	Max	Unit
tVSL	VCC(min) To CS# Low	10			us
tPUW	Time Delay Before Write Instruction	1		10	ms
VWI	Write Inhibit Voltage	2.1	2.3	2.5	V

### 8.2. INITIAL DELIVERY STATE

The device is delivered with the memory array erased: all bits are set to 1(each byte contains FFH). The Status Register contains 00H (all Status Register bits are 0).

### 8.3. DATA RETENTION AND ENDURANCE

Parameter	Test Condition	Min	Units
Minimum Pottorn Data Patantian Time	150℃	10	Years Years
Minimum Pattern Data Retention Time	125℃	20	Years
Erase/Program Endurance	-40 to 85℃	100K	Cycles

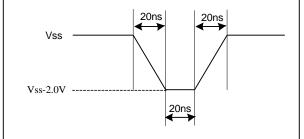


### **8.4. ABSOLUTE MAXIMUM RATINGS**

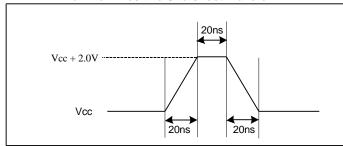
Parameter	Value	Unit
Ambient Operating Temperature	-40 to 85	°C
Storage Temperature	-65 to 150	°C
Output Short Circuit Current	200	mA
Applied Input / Output Voltage	-0.6 to VCC+0.4	V
Transient Input / Output Voltage	-2.0 to VCC+2.0	V
VCC	-0.6 to VCC+0.4	V

Figure 36. Maximum Negative and Positive Overshoot Waveform

### **Maximum Negative Overshoot Waveform**



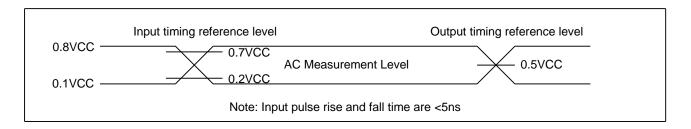
**Maximum Positive Overshoot Waveform** 



### 8.5. CAPACITANCE MEASUREMENT CONDITIONS

Symbol	Parameter	Min	Тур	Max	Unit	Conditions
CIN	Input Capacitance			6	pF	VIN=0V
COUT	Output Capacitance			8	pF	VOUT=0V
CL	Load Capacitance		30			
	Input Rise And Fall time			5	ns	
	Input Pulse Voltage	0.1VC	C to 0.8V0	CC	V	
	Input Timing Reference Voltage	0.2VC	0.2VCC to 0.7VCC		V	
	Output Timing Reference Voltage		0.5VCC		V	

Figure 37:Input Test Waveform and Measurement Level





# 8.6. DC CHARACTERISTICS

(T= -40°C~85°C, VCC=2.7~3.6V)

Symbol	Parameter	Test Condition	Min.	Тур	Max.	Unit.
lu	Input Leakage Current				±2	μΑ
ILO	Output Leakage Current				±2	μΑ
Icc1	Standby Current	CS#=VCC,		1	5	μA
		V <sub>IN</sub> =VCC or VSS				
I <sub>CC2</sub>	Deep Power-Down Current	CS#=VCC,		1	5	μA
		V <sub>IN</sub> =VCC or VSS				
		CLK=0.1VCC / 0.9VCC				
		at 120MHz,		15	20	mA
Іссз	Operating Current (Read)	Q=Open(*1,*2,*4 I/O)				
ICC3	Operating Current (Neau)	CLK=0.1VCC / 0.9VCC				
		at 80MHz,		13	18	mA
		Q=Open(*1,*2,*4 I/O)				
I <sub>CC4</sub>	Operating Current (PP)	CS#=VCC			20	mA
I <sub>CC5</sub>	Operating Current(WRSR)	CS#=VCC			20	mA
Icc6	Operating Current (SE)	CS#=VCC			20	mA
Icc7	Operating Current (BE)	CS#=VCC			20	mA
I <sub>CC8</sub>	Operating Current (CE)	CS#=VCC			20	mA
Icc <sub>9</sub>	High Performance Current			400	800	uA
V <sub>IL</sub>	Input Low Voltage				0.2VCC	V
V <sub>IH</sub>	Input High Voltage		0.7VCC			V
Vol	Output Low Voltage	I <sub>OL</sub> =100uA			0.2	V
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> =-100μA	VCC-0.2			V

# 8.7. AC CHARACTERISTICS

 $(T=-40^{\circ}C-85^{\circ}C, VCC=2.7-3.6V, C_L=30pf)$ 

Symbol	Parameter	Min.	Тур.	Max.	Unit.
	Serial Clock Frequency For: Dual I/O(BBH),				
fc	Quad I/O(EBH), Quad Output(6BH) (Dual I/O & Quad I/O	DC.		104	MHz
	Without High Performance Mode), on 3.0V-3.6V power supply				
	Serial Clock Frequency For: Dual I/O(BBH),				
f <sub>C1</sub>	Quad I/O(EBH), Quad Output(6BH) (Dual I/O & Quad I/O	DC.		80	MHz
	Without High Performance Mode), on 2.7V-3.0V power supply				
	Serial Clock Frequency For: Dual I/O(BBH),				
f <sub>C2</sub>	Quad I/O(EBH), Quad Output(6BH) (Dual I/O & Quad I/O	DC.		120	MHz
	With High Performance Mode), on 2.7V-3.6V power supply				
$f_R$	Serial Clock Frequency For: Read(03H)	DC.		80	MHz
t <sub>CLH</sub>	Serial Clock High Time	4			ns
tcll	Serial Clock Low Time	4			ns
tclch	Serial Clock Rise Time (Slew Rate)	0.2			V/ns
t <sub>CHCL</sub>	Serial Clock Fall Time (Slew Rate)	0.2			V/ns
tslch	CS# Active Setup Time	5			ns
tchsh	CS# Active Hold Time	5			ns
tshch	CS# Not Active Setup Time	5			ns
tchsl	CS# Not Active Hold Time	5			ns
t <sub>SHSL</sub>	CS# High Time (read/write)	20			ns
<b>t</b> shqz	Output Disable Time			6	ns
tclqx	Output Hold Time	1.2			ns
t <sub>DVCH</sub>	Data In Setup Time	2			ns
tchdx	Data In Hold Time	2			ns
t <sub>HLCH</sub>	HOLD# Low Setup Time (relative to Clock)	5			ns
t <sub>HHCH</sub>	HOLD# High Setup Time (relative to Clock)	5			ns
tchhl	HOLD# High Hold Time (relative to Clock)	5			ns
tсннн	HOLD# Low Hold Time (relative to Clock)	5			ns
tHLQZ	HOLD# Low To High-Z Output			6	ns
thhqx	HOLD# High To Low-Z Output			6	ns
t <sub>CLQV</sub>	Clock Low To Output Valid			7	ns
twnsl	Write Protect Setup Time Before CS# Low	20			ns
tshwL	Write Protect Hold Time After CS# High	100			ns
t <sub>DP</sub>	CS# High To Deep Power-Down Mode			20	μs
	CS# High To Standby Mode Without Electronic Signature				
t <sub>RES1</sub>	Read			20	μs
t <sub>RES2</sub>	CS# High To Standby Mode With Electronic Signature Read			20	μs
tsus	CS# High To Next Command After Suspend			20	us
t <sub>RST</sub>	CS# High To Next Command After Reset			20	us
tw	Write Status Register Cycle Time		5	30	ms



# 3.3V Uniform Sector GigaDevice Dual and Quad Serial Flash

### **GD25Q16C**

t <sub>BP1</sub>	Byte Program Time( First Byte)	30	50	us
t <sub>BP2</sub>	Additional Byte Program Time ( After First Byte)	2.5	12	us
tpp	Page Programming Time	0.6	2.4	ms
tse	Sector Erase Time(4K Bytes)	45	150/300(1)	ms
t <sub>BE1</sub>	Block Erase Time(32K Bytes)	0.15	0.3/0.7 (2)	S
t <sub>BE2</sub>	Block Erase Time(64K Bytes)	0.25	0.5/0.8 (3)	S
tce	Chip Erase Time(GD25Q16C)	7	20	S

- 1. Max Value 4KB  $t_{SE}$  with<50K cycles is 150ms and >50K & <100k cycles is 300ms.
- 2. Max Value 32KB  $t_{BE}$  with<50K cycles is 0.3s and >50K & <100k cycles is 0.7s.
- 3. Max Value 64KB  $t_{BE}$  with<50K cycles is 0.5s and >50K & <100k cycles is 0.8s.

Figure 38. Serial Input Timing

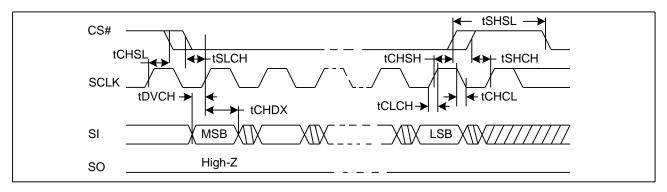


Figure 39. Output Timing

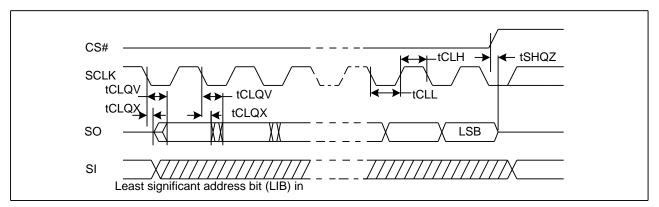
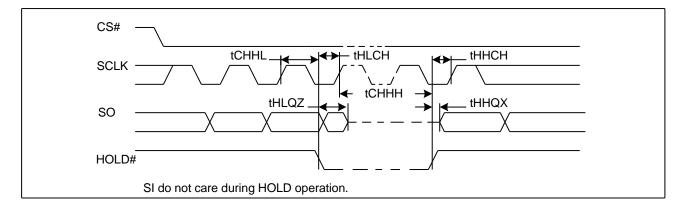
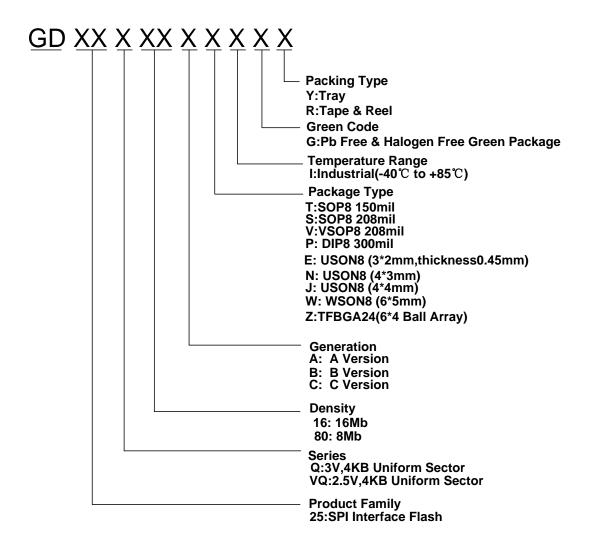


Figure 40. Hold Timing

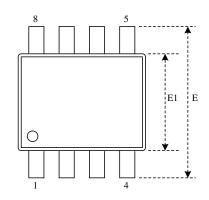


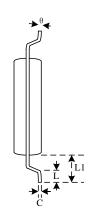
### 9. ORDERING INFORMATION

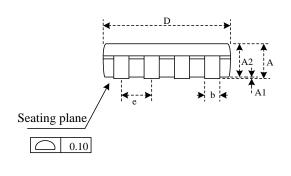


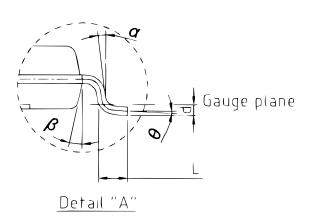
# **10. PACKAGE INFORMATION**

# 10.1. Package SOP8 150MIL



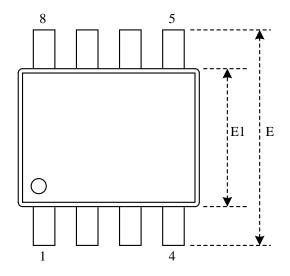


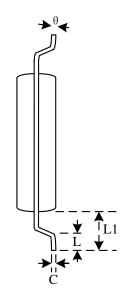


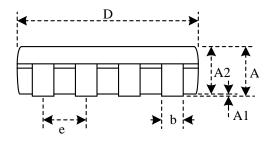


### **Dimensions**

Symbol				4.0		_	D	Е	E1	_		14	•		
Unit		Α	A1	A2	b	С	, D	_	E1	е	_	L1	θ	α	β
	Min	1.35	0.05	1.35	0.31	0.15	4.77	5.80	-	-	0.40	0.85	0°	6°	11°
mm	Nom	-	-	-	-	-	4.90	6.00	3.90	1.27	-	1.06	-	7°	12°
	Max	1.75	0.25	1.55	0.51	0.25	5.03	6.20	-	-	0.90	1.27	8°	8°	13°
	Min	0.053	0.002	0.053	0.012	0.006	0.188	0.228	-	-	0.016	0.033	0°	6°	11°
Inch	Nom	-	-	-	0.016	-	0.193	0.236	0.154	0.050	-	0.042	-	7°	12°
	Max	0.069	0.010	0.061	0.020	0.010	0.198	0.244	-	-	0.035	0.050	8°	8°	13°

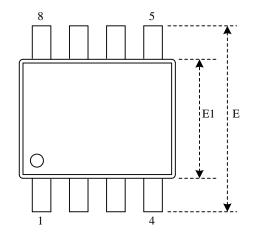


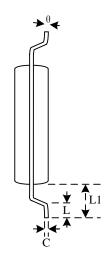


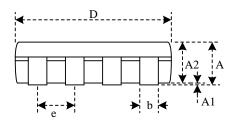


### **Dimensions**

Symb	ool	Α	A4	A2	h	С	D	E	E1			14	θ
Unit		A	A1	AZ	b		0	_	_ E1	е	_	L1	0
	Min		0.05	1.70	0.31	0.18	5.13	7.70	5.18		0.50	1.21	0
mm	Nom		0.15	1.80	0.41	0.21	5.23	7.90	5.28	1.27	0.67	1.31	5
	Max	2.16	0.25	1.91	0.51	0.25	5.33	8.10	5.38		0.85	1.41	8
	Min		0.002	0.067	0.012	0.007	0.202	0.303	0.204		0.020	0.048	0
Inch	Nom		0.006	0.071	0.016	0.008	0.206	0.311	0.208	0.050	0.026	0.052	5
	Max	0.085	0.010	0.075	0.020	0.010	0.210	0.319	0.212		0.033	0.056	8

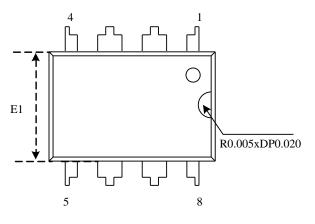


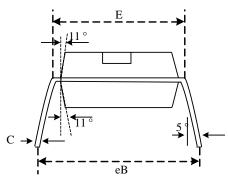


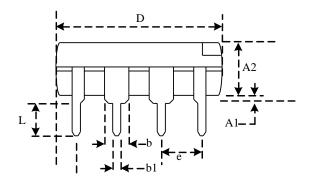


### **Dimensions**

	0110										
Syı	mbol	Α	A1	A2	b	D	Е	E1	•		θ
U	Jnit	A	AI	AL	"			E1	е	L	
	Min		0.05	0.75	0.35	5.18	7.70	5.18		0.50	0
mm	Nom		0.10	0.80	0.42	5.28	7.90	5.28	1.27	0.65	
	Max	1.00	0.15	0.85	0.48	5.38	8.10	5.38		0.80	10
	Min		0.002	0.030	0.014	0.204	0.303	0.204		0.020	0
Inch	Nom		0.004	0.032	0.016	0.206	0.311	0.206	0.050	0.026	
	Max	0.04	0.006	0.034	0.020	0.210	0.319	0.210		0.031	10



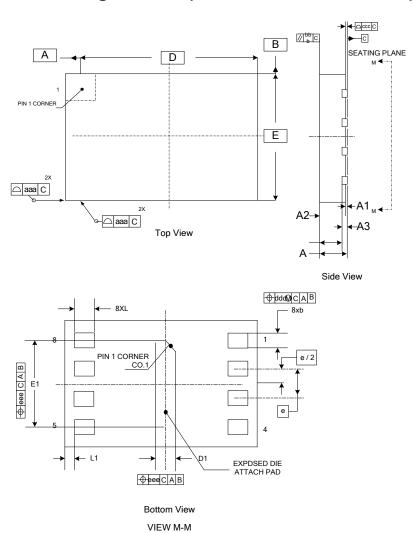




### **Dimensions**

Symb	ool	A1	A2	b	b1	С	D	E	E1		a B	
Unit		AI	AZ	D	ы	C	0	_	EI	е	eB	L
	Min	0.38	3.00	1.27	0.38	0.20	9.05	7.62	6.12		7.62	3.04
mm	Nom	0.72	3.25	1.46	0.46	0.28	9.32	7.94	6.38	2.54	8.49	3.30
	Max	1.05	3.50	1.65	0.54	0.34	9.59	8.26	6.64		9.35	3.56
	Min	0.015	0.118	0.05	0.015	0.008	0.356	0.300	0.242		0.333	0.12
Inch	Nom	0.028	0.128	0.058	0.018	0.011	0.367	0.313	0.252	0.1	0.345	0.13
	Max	0.041	0.138	0.065	0.021	0.014	0.378	0.326	0.262		0.357	0.14

# 10.5. Package USON8 (3\*2mm, thickness 0.45mm)

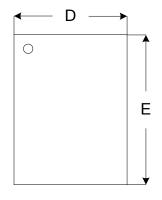


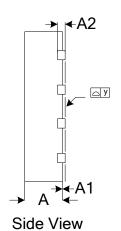
### **Dimensions**

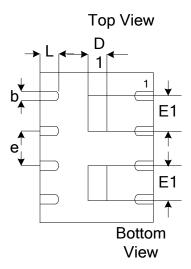
Symb	ool			40	40			_	_		14	
Unit		Α	A1	A2	A3	b	D	E	е	J	K	L
	Min	0.40	0.00	0.25		0.20	2.90	1.90		0.15	1.55	0.30
mm	Nom	0.45		0.30	0.150	0.25	3.00	2.00	0.5	0.20	1.60	0.35
	Max	0.50	0.05	0.35	REF	0.30	3.10	2.10	BSC	0.25	1.65	0.40
	Min	0.015	0.00	0.009	0.005	0.007	0.114	0.074	0.019	0.005	0.061	0.011
Inch	Nom	0.018		0.012	REF	0.010	0.118	0.079	BSC	0.008	0.063	0.014
	Max	0.019	0.001	0.013		0.012	0.122	0.082		0.009	0.064	0.015

- 1. Both package length and width do not include mold flash.
- 2. The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.

# 10.6. Package USON8 (4\*3mm)





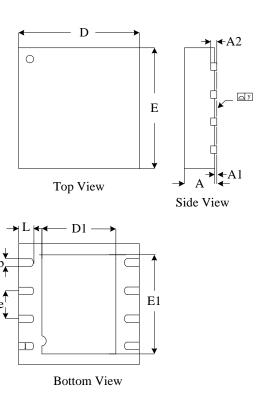


### **Dimensions**

Symb	ool	_	A.1	A2	<b>L</b>	D	D1	E	E1		.,	
Unit		A	A1	AZ	b	U	וט	_	_ E1	е	У	L
	Min	0.50	0.00		0.25	2.90	0.10	3.90	0.70		0.00	0.50
mm	Nom	0.55		0.15	0.30	3.00	0.25	4.00	0.80	0.80		0.60
	Max	0.60	0.05		0.35	3.10	0.40	4.10	0.90		0.08	0.70
	Min	0.020	0.000		0.010	0.114	0.004	0.153	0.027		0.000	0.020
Inch	Nom	0.022		0.006	0.012	0.118	0.010	0.157	0.031	0.031		0.024
	Max	0.024	0.002		0.014	0.122	0.016	0.161	0.035		0.003	0.028

- 1. Both package length and width do not include mold flash.
- 2. The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.

# 10.7. Package USON8 (4\*4mm)

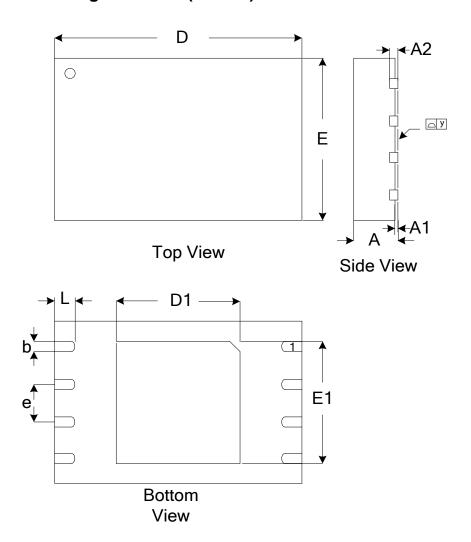


### **Dimensions**

Symb	ool		A4	4.2	<b>b</b>	D	D1	E	E1			
Unit		Α	A1	A2	b	D	וט		EI	е		
	Min	0.50			0.25	3.90	2.20	3.90	2.60		0.35	
mm	Nom	0.55		0.15BSC	0.30	4.00	2.30	4.00	2.70	0.80BSC	0.40	
	Max	0.60	0.05		0.35	4.10	2.40	4.10	2.80		0.45	
	Min	0.020			0.010	0.153	0.087	0.153	0.102		0.014	
Inch	Nom	0.022		0.006BSC	0.012	0.157	0.091	0.157	0.106	0.031BSC	0.016	
	Max	0.024	0.002		0.014	0.161	0.095	0.161	0.110		0.018	

- 1. Both package length and width do not include mold flash.
- 2. The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.

# 10.8. Package WSON 8 (6\*5mm)

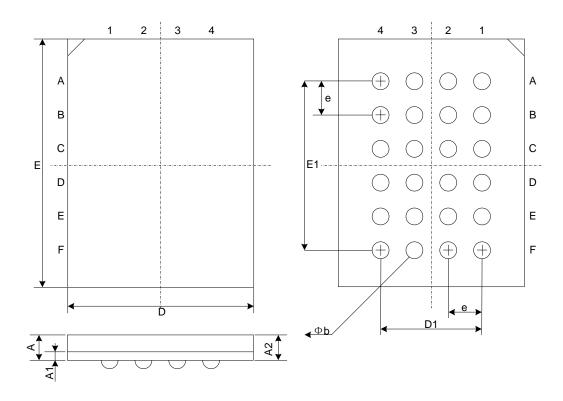


### **Dimensions**

	Zimensions											
Syml	ool	Α	A1	A2	b	D	D1	Е	E1		.,	
Unit		A	AI	AZ	5		וט	_	E1	е	У	_
	Min	0.70		0.19	0.35	5.90	3.25	4.90	3.85		0.00	0.50
mm	Nom	0.75		0.22	0.42	6.00	3.37	5.00	3.97	1.27 BSC	0.04	0.60
	Max	0.80	0.05	0.25	0.48	6.10	3.50	5.10	4.10		0.08	0.75
	Min	0.028		0.007	0.014	0.232	0.128	0.193	0.151		0.000	0.020
Inch	Nom	0.030		0.009	0.016	0.236	0.133	0.197	0.156	0.05 BSC	0.001	0.024
	Max	0.032	0.002	0.010	0.019	0.240	0.138	0.201	0.161		0.003	0.030

- 1. Both package length and width do not include mold flash.
- 2. The exposed metal pad area on the bottom of the package is connected to device ground (GND pin), so both Floating and connecting GND of exposed pad are also available.

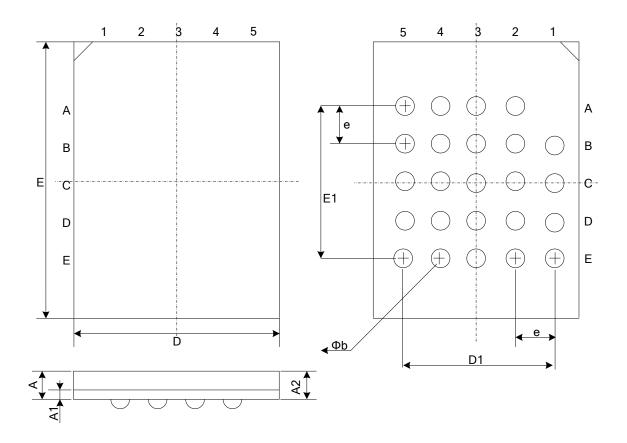
# 10.9. Package TFBGA-24BALL (6\*4 ball array)



### **Dimensions**

Symbo	ol			40			<b>D4</b>	_	F4	_
Unit		Α	A1	A2	b	D	D1	E	E1	е
	Min		0.25		0.35	5.90		7.90		
mm	Nom		0.30	0.85	0.40	6.00	3.00	8.00	5.00	1.00
	Max	1.20	0.35		0.45	6.10		8.10		
	Min		0.010		0.014	0.232		0.311		
Inch	Nom		0.012	0.033	0.016	0.236	0.120	0.315	0.200	0.039
	Max	0.047	0.014		0.018	0.240		0.319		

# 10.10. Package TFBGA-24BALL (5\*5 ball array)



### **Dimensions**

Symbo	ol			40		_	D4	_	F4	_
Unit		A	A1	A2	b	D	D1	E	E1	е
	Min		0.25		0.35	5.90		7.90		
mm	Nom		0.30		0.40	6.00	4.00	8.00	4.00	1.00
	Max	1.20	0.35		0.45	6.10		8.10		
	Min		0.010	0.033	0.014	0.232		0.311		
Inch	Nom		0.012		0.016	0.236	0.157	0.315	0.157	0.039
	Max	0.047	0.014		0.018	0.240		0.319		



# 11. REVISION HISTORY

Version No	Description	Date
1.0	Initial Release	2015-7-23
4.4	Modify ORDERING INFORMATION	2045 7 24
1.1	Modify PACKAGE INFORMATION	2015-7-31